Cat.No.C49E-22

EU RoHS Compliant

- \cdot All the products in this catalog comply with EU RoHS.
- EU RoHS is "the European Directive 2011/65/EU on the Restriction of the Use of Certain Hazardous Substances in Electrical and Electronic Equipment."
- · For more details, please refer to our website 'Murata's Approach for EU RoHS' (http://www.murata.com/info/rohs.html).



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¹∆Ca	ution
lotic	e –

Part Numbering

Radial Lead Type Monolithic Ceramic Capacitors

RC E R7 1H 104 K 0 M1 H03 A (Part Number)

Product ID

2Series/Terminal

Product ID	Series/Terminal	
RC	E	Radial Lead Type Monolithic Ceramic Capacitors 125°C max. (for Automotive) (DC25V-DC1kV)
RH	E	Radial Lead Type Monolithic Ceramic Capacitors 150°C max. (for Automotive) (DC50V-DC100V)
RD	E	Radial Lead Type Monolithic Ceramic Capacitors (Only for General Use) (DC25V-DC1kV)

3Temperature Characteristics

Code	Temperature Characteristics	Reference Temperature	Temperature Range	Capacitance Change or Temperature Coefficient	Operating Temperature Range
5C	C0G*	25°C	25 to 125°C	0±30ppm/°C	-55 to 125°C
5G	X8G*	25°C	25 to 150°C	0±30ppm/°C	-55 to 150°C
7U	U2J	25°C	25 to 125°C	-750±120ppm/°C	-55 to 125°C
C7	X7S	25°C	-55 to 125°C	±22%	-55 to 125°C
D7	X7T	25°C	-55 to 125°C	+22, -33%	-55 to 125°C
F1	F	20°C	-25 to 85°C	+30, -80%	-25 to 85°C
F5	Y5V	25°C	-30 to 85°C	+22, -82%	-30 to 85°C
L8	X8L	25°C	-55 to 125°C	±15%	-55 to 150°C
LO	AOL	25 C	125 to 150°C	+15, -40%	-55 to 150 C
R7	X7R	25°C	-55 to 125°C	±15%	-55 to 125°C

^{*} Please refer to table for Capacitance change under reference temperature.

[·] Capacitance change from each temperature

		Capacitance Change from 25°C (%)								
Char.	Nominal Values (ppm/°C) *1	-55	5°C	-30)°C	-10°C				
		Max.	Min.	Max.	Min.	Max.	Min.			
COG	0±30	0.58	-0.24	0.40	-0.17	0.25	-0.11			
X8G	0±30	0.56	-0.24	0.40	-0.17	0.25	-0.11			
U2J	-750±120	8.78	5.04	6.04	3.47	3.84	2.21			

^{*1:} Nominal values denote the temperature coefficient within a range of 25 to 125°C.

4Rated Voltage

Code	Rated Voltage
1E	DC25V
1H	DC50V
2A	DC100V
2E	DC250V
2W	DC450V
2J	DC630V
3A	DC1kV

6 Capacitance

Expressed by three figures. The unit is pico-farad (pF). The first and second figures are significant digits, and the third figure expresses the number of zeros that follow the two numbers. If there is a decimal point, it is expressed by the capital letter "R." In this case, all figures are significant digits.

6Capacitance Tolerance

Code	Capacitance Tolerance	Temperature Characteristics	Capacitance Step		
С	±0.25pF		≦5pF : 1pF Step		
D	±0.5pF	C0G/X8G	6 to 9pF : 1pF Step		
J	±5%		≥10 : E12 Series		
K	±10%	X7S/X7T/X7R/ X8L	E6 Series		
М	±20%	X7S/X7T/ X7R/X8L	E3 Series		
Z	+80%, -20%	F/Y5V	E3 Series		





 $\begin{tabular}{|c|c|c|c|c|} \hline \end{tabular}$ Continued from the preceding page.

Dimensions (LxW)

Code	Dimensions (LxW)					
0	3.6×3.5mm or 4.0×3.5mm or 5.0×3.5mm (Depends on Part Number List)					
1	4.0×3.5mm or 4.5×3.5mm or 5.0×3.5mm (Depends on Part Number List)					
2	5.5×4.0mm					
3	5.5×5.0mm					
4	7.5×5.5mm					
5	7.5×7.5mm (DC630V, DC1kV: 7.5×8.0mm)					
U	7.7×12.5mm (DC630V, DC1kV: 7.7×13.0mm)					
W	5.5×7.5mm					

8 Lead Style

Code	Lead Style	Lead Spacing
A2	Straight Long	2.5mm
B1	Straight Long	5.0mm
DB	Straight Taping	2.5mm
E1/E2	Straight Taping	5.0mm
K1	Inside Crimp	5.0mm
M1/M2	Inside Crimp Taping	5.0mm
P1	Outside Crimp	2.5mm
S1/S2	Outside Crimp Taping	2.5mm

Lead distance between reference and bottom planes.

M1, S1, DB : $H_0 = 16.0\pm0.5$ mm M2, S2 : $H_0 = 20.0\pm0.5$ mm E1 : $H = 17.5\pm0.5$ mm E2 : $H = 20.0\pm0.5$ mm

Individual Specification Code Expressed by three figures

Packaging

Code	Packaging
Α	Ammo Pack
В	Bulk



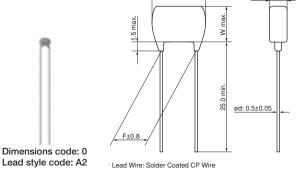
Radial Lead Type Monolithic Ceramic Capacitors



RCE Series 125°C max. (for Automotive) (DC25V-DC1kV)

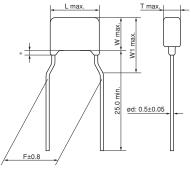
■ Features

- 1. Small size and large capacitance
- 2. Low ESR and ESL suitable for high frequency
- 3. Meet AEC-Q200, ISO7637-2 (surge test) requirement
- 4. Meet LF (Lead Free) and HF (Halogen Free)
- 5. Flow soldering and welding are available. (Re-flow soldering is not available.)
- 6. If copper wire is necessary at welding process, copper wire is available based on request.

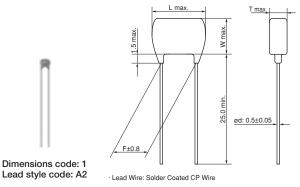


(in mm)



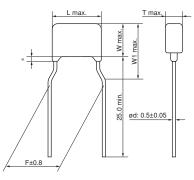


Coating extension does not exceed the end of the lead bend Lead Wire: Solder Coated CP Wire



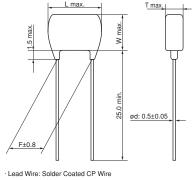
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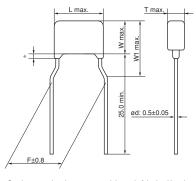
Coating extension does not exceed the end of the lead bend Lead Wire: Solder Coated CP Wire





(in mm)

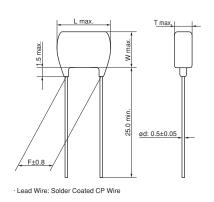




Coating extension does not exceed the end of the lead bend

Lead Wire: Solder Coated CP Wire

Dimensions code: 3 Lead style code: A2



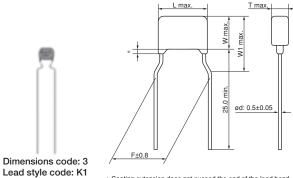




T max.



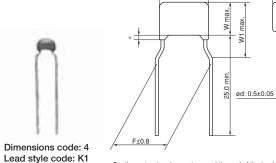
Continued from the preceding page.



- * Coating extension does not exceed the end of the lead bend.

 Lead Wire: Solder Coated CP Wire

(in mm)

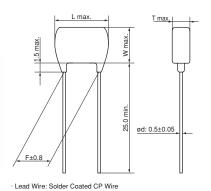


- * Coating extension does not exceed the end of the lead bend.
 Lead Wire: Solder Coated CP Wire

(in mm)



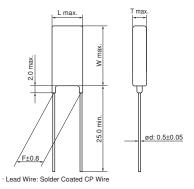
Dimensions code: 5 Lead style code: B1



(in mm)

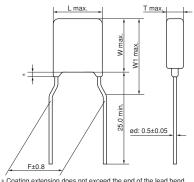


Dimensions code: U Lead style code: B1



(in mm)





Coating extension does not exceed the end of the lead bend.
Lead Wire: Solder Coated CP Wire

(in mm)

■ Dimensions

Dimensions and				Dimensions (mm)		
Lead Style Code	L	W	W1	Т	F	d
0A2/0DB	3.6	3.5	-		2.5	0.5
0K1/0M1	3.6	3.5	6.0		5.0	0.5
1A2/1DB	4.0	3.5	-		2.5	0.5
1K1/1M1	4.0	3.5	5.0		5.0	0.5
2A2/2DB	5.5	4.0	-		2.5	0.5
2K1/2M1	5.5	4.0	6.0	See the individual	5.0	0.5
3A2/3DB	5.5	5.0	-	product specification	2.5	0.5
3K1/3M1	5.5	5.0	7.5		5.0	0.5
4K1/4M1	7.5	5.5	8.0		5.0	0.5
5B1/5E1	7.5	7.5*	-		5.0	0.5
UB1/UE1	7.7	12.5*	-		5.0	0.5
WK1/WM1	5.5	7.5	10.0		5.0	0.5
*DCC201/ DC11-1/- M - 0 6						

*DC630V, DC1kV: W+0.5mm

■ Marking

	ated oltage	DC	25V		DC50V			DC100V		DC250V	DC630V	DC1kV
	emp. har.	X7S	X7R	C0G	X7S	X7R	C0G	X7S	X7R		X7R, U2J	
0		224K	104K	A	-	224K	A	_	224K	_	_	_
1			-	102J	-		102J	_		U 102J	_	_
2		(M 475) K2C	-	-	(M 475) K5C	105 K5C	-	-	(M 105 K1C)	(U2J) (U2J) (X7R)	(U2J) 153 (X7R)	102 JAU (U2J) (U2J) (X7R)
3, 4, W		(M226 K2C)	-	-	-	(M335 K5C)	-	(M225 K1C)	_	(W473 J4U (U2J) (W224 K4C (X7R)	(M103 J7U (U2J) (M104 K7C (X7R)	(U2J) (X7R)
5, U		-	-	-	-	-	-	-	-	- (M 474 K4C (X7R)	(W2J) (U2J) (U2J) (M474 M7C (X7R)	(U2J) (U2J) (M104 KAC (X7R)
Temperature Characteristics				G char.: A, se refer to t		nar.: C, U2J example.)	char.: U)					
Nominal Capacita	ance	Under 100	pF: Actual v	alue 100p	F and over	: Marked wi	th 3 figures					
Capacitance Tolera		Marked with code A part is omitted (Please refer to the marking example.)										
Rated Voltage				25V: 2, DC se refer to t			250V: 4, D0	C630V: 7, D	C1kV: A)			
Manufacturer's Identification		Marked wit A part is or		se refer to t	he marking	example.)						

Temperature Compensating Type, C0G/U2J Characteristics

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RCE5C1H1R0C0□□H03□	C0G (EIA)	50Vdc	1.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H1R0C0□□H03□	C0G (EIA)	50Vdc	1.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H2R0C0□□H03□	C0G (EIA)	50Vdc	2.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H2R0C0□□H03□	C0G (EIA)	50Vdc	2.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H3R0C0□□H03□	C0G (EIA)	50Vdc	3.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H3R0C0□□H03□	C0G (EIA)	50Vdc	3.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H4R0C0□□H03□	C0G (EIA)	50Vdc	4.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H4R0C0□□H03□	C0G (EIA)	50Vdc	4.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H5R0C0□□H03□	C0G (EIA)	50Vdc	5.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H5R0C0□□H03□	C0G (EIA)	50Vdc	5.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H6R0D0□□H03□	C0G (EIA)	50Vdc	6.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H6R0D0□□H03□	C0G (EIA)	50Vdc	6.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H7R0D0□□H03□	C0G (EIA)	50Vdc	7.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H7R0D0□□H03□	C0G (EIA)	50Vdc	7.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H8R0D0□□H03□	C0G (EIA)	50Vdc	8.0pF±5%	3.6×3.5	2.5	2.5	A2	DB

muRata

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RCE5C1H8R0D0□□H03□	C0G (EIA)	50Vdc	8.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H9R0D0□□H03□	C0G (EIA)	50Vdc	9.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H9R0D0□□H03□	C0G (EIA)	50Vdc	9.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H100J0□□H03□	C0G (EIA)	50Vdc	10pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H100J0□□H03□	C0G (EIA)	50Vdc	10pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H120J0□□H03□	C0G (EIA)	50Vdc	12pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H120J0□□H03□	C0G (EIA)	50Vdc	12pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H150J0□□H03□	C0G (EIA)	50Vdc	15pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H150J0□□H03□	C0G (EIA)	50Vdc	15pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H180J0□□H03□	C0G (EIA)	50Vdc	18pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H180J0□□H03□	C0G (EIA)	50Vdc	18pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H220J0□□H03□	C0G (EIA)	50Vdc	22pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H220J0□□H03□	C0G (EIA)	50Vdc	22pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H270J0□□H03□	C0G (EIA)	50Vdc	27pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H270J0□□H03□	C0G (EIA)	50Vdc	27pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H330J0□□H03□	C0G (EIA)	50Vdc	33pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H330J0□□H03□	C0G (EIA)	50Vdc	33pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H390J0□□H03□	C0G (EIA)	50Vdc	39pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H390J0□□H03□	C0G (EIA)	50Vdc	39pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H470J0□□H03□	C0G (EIA)	50Vdc	47pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H470J0□□H03□	C0G (EIA)	50Vdc	47pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H560J0□□H03□	C0G (EIA)	50Vdc	56pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H560J0□□H03□	C0G (EIA)	50Vdc	56pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H680J0□□H03□	C0G (EIA)	50Vdc	68pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H680J0□□H03□	C0G (EIA)	50Vdc	68pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H820J0□□H03□	C0G (EIA)	50Vdc	82pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H820J0□□H03□	C0G (EIA)	50Vdc	82pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H101J0 H03	C0G (EIA)	50Vdc	100pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H101J0 H03	COG (EIA)	50Vdc	100pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H121J0 H03	COG (EIA)	50Vdc	120pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H121J0 H03	COG (EIA)	50Vdc	120pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H151J0 H03	COG (EIA)	50Vdc	150pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H151J0 H03	COG (EIA)	50Vdc	150pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H181J0 H03	COG (EIA)	50Vdc	180pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H181J0 H03	COG (EIA)	50Vdc	180pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H221J0 H03	COG (EIA)	50Vdc	220pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H221J0 H03	COG (EIA)	50Vdc	220pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H271J0□□H03□ RCE5C1H271J0□□H03□	COG (EIA)	50Vdc 50Vdc	270pF±5%	3.6×3.5	2.5	2.5	A2 K1	DB M1
RCE5C1H271J0	COG (EIA)	50Vdc 50Vdc	270pF±5% 330pF±5%	3.6×3.5 3.6×3.5	2.5	5.0 2.5	A2	M1 DB
RCE5C1H331J0 H03	COG (EIA)	50Vdc	330pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H391J0 H03	COG (EIA)	50Vdc	390pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H391J0	COG (EIA)	50Vdc	390pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H471J0 H03	COG (EIA)	50Vdc	470pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H471J0 H03	COG (EIA)	50Vdc	470pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H561J0 H03	COG (EIA)	50Vdc	560pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H561J0 H03	COG (EIA)	50Vdc	560pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H681J0□□H03□	COG (EIA)	50Vdc	680pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H681J0□□H03□	COG (EIA)	50Vdc	680pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H821J0□□H03□	COG (EIA)	50Vdc	820pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H821J0□□H03□	COG (EIA)	50Vdc	820pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H102J0□□H03□	COG (EIA)	50Vdc	1000pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H102J0□□H03□	COG (EIA)	50Vdc	1000pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H122J0□□H03□	COG (EIA)	50Vdc	1200pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H122J0□□H03□	COG (EIA)	50Vdc	1200pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H152J0□□H03□	COG (EIA)	50Vdc	1500pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H152J0□□H03□	COG (EIA)	50Vdc	1500pF±5%	3.6×3.5	2.5	5.0	K1	M1

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RCE5C1H182J0□□H03□	C0G (EIA)	50Vdc	1800pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H182J0□□H03□	COG (EIA)	50Vdc	1800pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H222J0□□H03□	COG (EIA)	50Vdc	2200pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H222J0□□H03□	C0G (EIA)	50Vdc	2200pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H272J0□□H03□	C0G (EIA)	50Vdc	2700pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H272J0□□H03□	C0G (EIA)	50Vdc	2700pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H332J0□□H03□	C0G (EIA)	50Vdc	3300pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H332J0□□H03□	C0G (EIA)	50Vdc	3300pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H392J0□□H03□	C0G (EIA)	50Vdc	3900pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C1H392J0□□H03□	C0G (EIA)	50Vdc	3900pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C1H472J1□□H03□	C0G (EIA)	50Vdc	4700pF±5%	4.0×3.5	2.5	2.5	A2	DB
RCE5C1H472J1□□H03□	C0G (EIA)	50Vdc	4700pF±5%	4.0×3.5	2.5	5.0	K1	M1
RCE5C1H562J1□□H03□	C0G (EIA)	50Vdc	5600pF±5%	4.0×3.5	2.5	2.5	A2	DB
RCE5C1H562J1□□H03□	C0G (EIA)	50Vdc	5600pF±5%	4.0×3.5	2.5	5.0	K1	M1
RCE5C1H682J1□□H03□	C0G (EIA)	50Vdc	6800pF±5%	4.0×3.5	2.5	2.5	A2	DB
RCE5C1H682J1□□H03□	C0G (EIA)	50Vdc	6800pF±5%	4.0×3.5	2.5	5.0	K1	M1
RCE5C1H822J1□□H03□	C0G (EIA)	50Vdc	8200pF±5%	4.0×3.5	2.5	2.5	A2	DB
RCE5C1H822J1□□H03□	C0G (EIA)	50Vdc	8200pF±5%	4.0×3.5	2.5	5.0	K1	M1
RCE5C1H103J1□□H03□	C0G (EIA)	50Vdc	10000pF±5%	4.0×3.5	2.5	2.5	A2	DB
RCE5C1H103J1□□H03□	C0G (EIA)	50Vdc	10000pF±5%	4.0×3.5	2.5	5.0	K1	M1
RCE5C1H123J1□□H03□	C0G (EIA)	50Vdc	12000pF±5%	4.0×3.5	2.5	2.5	A2	DB
RCE5C1H123J1□□H03□	C0G (EIA)	50Vdc	12000pF±5%	4.0×3.5	2.5	5.0	K1	M1
RCE5C1H153J1□□H03□	C0G (EIA)	50Vdc	15000pF±5%	4.0×3.5	2.5	2.5	A2	DB
RCE5C1H153J1□□H03□	C0G (EIA)	50Vdc	15000pF±5%	4.0×3.5	2.5	5.0	K1	M1
RCE5C1H183J1□□H03□	C0G (EIA)	50Vdc	18000pF±5%	4.0×3.5	2.5	2.5	A2	DB
RCE5C1H183J1□□H03□	C0G (EIA)	50Vdc	18000pF±5%	4.0×3.5	2.5	5.0	K1	M1
RCE5C1H223J1□□H03□	C0G (EIA)	50Vdc	22000pF±5%	4.0×3.5	2.5	2.5	A2	DB
RCE5C1H223J1□□H03□	C0G (EIA)	50Vdc	22000pF±5%	4.0×3.5	2.5	5.0	K1	M1
RCE5C2A1R0C0□□H03□	C0G (EIA)	100Vdc	1.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A1R0C0□□H03□	C0G (EIA)	100Vdc	1.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A2R0C0□□H03□	C0G (EIA)	100Vdc	2.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A2R0C0□□H03□	C0G (EIA)	100Vdc	2.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A3R0C0□□H03□	C0G (EIA)	100Vdc	3.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A3R0C0□□H03□	C0G (EIA)	100Vdc	3.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A4R0C0 H03	C0G (EIA)	100Vdc	4.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A4R0C0 H03	C0G (EIA)	100Vdc	4.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A5R0C0□□H03□	C0G (EIA)	100Vdc	5.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A5R0C0□□H03□	C0G (EIA)	100Vdc	5.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A6R0D0 H03	C0G (EIA)	100Vdc	6.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A6R0D0 H03	COG (EIA)	100Vdc	6.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A7R0D0 H03	COG (EIA)	100Vdc	7.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A7R0D0 H03	COG (EIA)	100Vdc	7.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A8R0D0 H03	COG (EIA)	100Vdc	8.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A8R0D0 H03	COG (EIA)	100Vdc	8.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A9R0D0 H03	COG (EIA)	100Vdc	9.0pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A9R0D0 H03	COG (EIA)	100Vdc	9.0pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A100J0 H03	COG (EIA)	100Vdc	10pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A100J0 H03	COG (EIA)	100Vdc	10pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A120J0 H03	COG (EIA)	100Vdc	12pF±5%	3.6×3.5	2.5	2.5	A2	DB M1
RCE5C2A120J0 H03	COG (EIA)	100Vdc	12pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A150J0 H03	COG (EIA)	100Vdc	15pF±5%	3.6×3.5	2.5	2.5	A2	DB M1
RCE5C2A190 IO H03	COG (EIA)	100Vdc	15pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A180J0 H03	COG (EIA)	100Vdc	18pF±5%	3.6×3.5	2.5	2.5	A2	DB M1
RCE5C2A180J0 H03	COG (EIA)	100Vdc	18pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A220J0 H03	COG (EIA)	100Vdc	22pF±5%	3.6×3.5	2.5	2.5	A2	DB M1
RCE5C2A220J0 H03	COG (EIA)	100Vdc	22pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A270J0□□H03□	C0G (EIA)	100Vdc	27pF±5%	3.6×3.5	2.5	2.5	A2	DB



Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RCE5C2A270J0□□H03□	C0G (EIA)	100Vdc	27pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A330J0□□H03□	C0G (EIA)	100Vdc	33pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A330J0□□H03□	C0G (EIA)	100Vdc	33pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A390J0□□H03□	C0G (EIA)	100Vdc	39pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A390J0□□H03□	C0G (EIA)	100Vdc	39pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A470J0□□H03□	C0G (EIA)	100Vdc	47pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A470J0□□H03□	C0G (EIA)	100Vdc	47pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A560J0□□H03□	C0G (EIA)	100Vdc	56pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A560J0□□H03□	C0G (EIA)	100Vdc	56pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A680J0□□H03□	C0G (EIA)	100Vdc	68pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A680J0□□H03□	C0G (EIA)	100Vdc	68pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A820J0□□H03□	C0G (EIA)	100Vdc	82pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A820J0□□H03□	C0G (EIA)	100Vdc	82pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A101J0□□H03□	C0G (EIA)	100Vdc	100pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A101J0□□H03□	C0G (EIA)	100Vdc	100pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A121J0□□H03□	C0G (EIA)	100Vdc	120pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A121J0□□H03□	C0G (EIA)	100Vdc	120pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A151J0□□H03□	C0G (EIA)	100Vdc	150pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A151J0□□H03□	C0G (EIA)	100Vdc	150pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A181J0□□H03□	C0G (EIA)	100Vdc	180pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A181J0□□H03□	C0G (EIA)	100Vdc	180pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A221J0□□H03□	C0G (EIA)	100Vdc	220pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A221J0□□H03□	C0G (EIA)	100Vdc	220pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A271J0□□H03□	C0G (EIA)	100Vdc	270pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A271J0□□H03□	C0G (EIA)	100Vdc	270pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A331J0□□H03□	C0G (EIA)	100Vdc	330pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A331J0□□H03□	C0G (EIA)	100Vdc	330pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A391J0□□H03□	C0G (EIA)	100Vdc	390pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A391J0□□H03□	C0G (EIA)	100Vdc	390pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A471J0□□H03□	C0G (EIA)	100Vdc	470pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A471J0□□H03□	C0G (EIA)	100Vdc	470pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A561J0□□H03□	C0G (EIA)	100Vdc	560pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A561J0□□H03□	C0G (EIA)	100Vdc	560pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A681J0□□H03□	C0G (EIA)	100Vdc	680pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A681J0□□H03□	C0G (EIA)	100Vdc	680pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A821J0□□H03□	C0G (EIA)	100Vdc	820pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A821J0□□H03□	C0G (EIA)	100Vdc	820pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A102J0□□H03□	C0G (EIA)	100Vdc	1000pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A102J0□□H03□	C0G (EIA)	100Vdc	1000pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A122J0□□H03□	C0G (EIA)	100Vdc	1200pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A122J0□□H03□	C0G (EIA)	100Vdc	1200pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A152J0□□H03□	C0G (EIA)	100Vdc	1500pF±5%	3.6×3.5	2.5	2.5	A2	DB
RCE5C2A152J0□□H03□	C0G (EIA)	100Vdc	1500pF±5%	3.6×3.5	2.5	5.0	K1	M1
RCE5C2A182J1□□H03□	C0G (EIA)	100Vdc	1800pF±5%	4.0×3.5	2.5	2.5	A2	DB
RCE5C2A182J1□□H03□	C0G (EIA)	100Vdc	1800pF±5%	4.0×3.5	2.5	5.0	K1	M1
RCE5C2A222J1□□H03□	C0G (EIA)	100Vdc	2200pF±5%	4.0×3.5	2.5	2.5	A2	DB
RCE5C2A222J1□□H03□	C0G (EIA)	100Vdc	2200pF±5%	4.0×3.5	2.5	5.0	K1	M1
RCE5C2A272J1□□H03□	C0G (EIA)	100Vdc	2700pF±5%	4.0×3.5	2.5	2.5	A2	DB
RCE5C2A272J1□□H03□	C0G (EIA)	100Vdc	2700pF±5%	4.0×3.5	2.5	5.0	K1	M1
RCE5C2A332J1□□H03□	C0G (EIA)	100Vdc	3300pF±5%	4.0×3.5	2.5	2.5	A2	DB
RCE5C2A332J1□□H03□	C0G (EIA)	100Vdc	3300pF±5%	4.0×3.5	2.5	5.0	K1	M1
RCE7U2E101J1□□H03□	U2J (EIA)	250Vdc	100pF±5%	4.0×3.5	3.15	5.0	K1	M1
RCE7U2E151J1□□H03□	U2J (EIA)	250Vdc	150pF±5%	4.0×3.5	3.15	5.0	K1	M1
RCE7U2E221J1□□H03□	U2J (EIA)	250Vdc	220pF±5%	4.0×3.5	3.15	5.0	K1	M1
RCE7U2E331J1□□H03□	U2J (EIA)	250Vdc	330pF±5%	4.0×3.5	3.15	5.0	K1	M1
RCE7U2E471J1□□H03□	U2J (EIA)	250Vdc	470pF±5%	4.0×3.5	3.15	5.0	K1	M1
RCE7U2E681J1□□H03□	U2J (EIA)	250Vdc	680pF±5%	4.0×3.5	3.15	5.0	K1	M1

Continued from the preceding page.

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RCE7U2E102J1□□H03□	U2J (EIA)	250Vdc	1000pF±5%	4.0×3.5	3.15	5.0	K1	M1
RCE7U2E152J1□□H03□	U2J (EIA)	250Vdc	1500pF±5%	4.0×3.5	3.15	5.0	K1	M1
RCE7U2E222J1□□H03□	U2J (EIA)	250Vdc	2200pF±5%	4.0×3.5	3.15	5.0	K1	M1
RCE7U2E332J1□□H03□	U2J (EIA)	250Vdc	3300pF±5%	4.0×3.5	3.15	5.0	K1	M1
RCE7U2E472J1□□H03□	U2J (EIA)	250Vdc	4700pF±5%	4.0×3.5	3.15	5.0	K1	M1
RCE7U2E682J2□□H03□	U2J (EIA)	250Vdc	6800pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2E103J2□□H03□	U2J (EIA)	250Vdc	10000pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J100J2□□H03□	U2J (EIA)	630Vdc	10pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J150J2□□H03□	U2J (EIA)	630Vdc	15pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J220J2□□H03□	U2J (EIA)	630Vdc	22pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J330J2□□H03□	U2J (EIA)	630Vdc	33pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J470J2 H03	U2J (EIA)	630Vdc	47pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J680J2 H03	U2J (EIA)	630Vdc	68pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J101J2 H03	U2J (EIA)	630Vdc	100pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J151J2 H03	U2J (EIA)	630Vdc	150pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J221J2 H03	U2J (EIA)	630Vdc	220pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J331J2 H03	U2J (EIA)	630Vdc	330pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J471J2 H03	U2J (EIA)	630Vdc	470pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J681J2□□H03□	U2J (EIA)	630Vdc	680pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J102J2 H03	U2J (EIA)	630Vdc		5.5×4.0	3.15	5.0	K1	M1
RCE7U2J152J2 H03	· , ,	630Vdc	1000pF±5%			5.0	K1	M1
	U2J (EIA)		1500pF±5%	5.5×4.0	3.15			
RCE7U2J222J2 H03	U2J (EIA)	630Vdc	2200pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J332J2 H03	U2J (EIA)	630Vdc	3300pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J472J2 H03	U2J (EIA)	630Vdc	4700pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U2J682J3	U2J (EIA)	630Vdc	6800pF±5%	5.5×5.0	4.0	5.0	K1	M1
RCE7U2J103J3	U2J (EIA)	630Vdc	10000pF±5%	5.5×5.0	4.0	5.0	K1	M1
RCE7U2J153J4 H03	U2J (EIA)	630Vdc	15000pF±5%	7.5×5.5	4.0	5.0	K1	M1
RCE7U2J223J4 H03	U2J (EIA)	630Vdc	22000pF±5%	7.5×5.5	4.0	5.0	K1	M1
RCE7U2J333J5 H03	U2J (EIA)	630Vdc	33000pF±5%	7.5×8.0	4.0	5.0	B1	E1
RCE7U2J473J5 H03	U2J (EIA)	630Vdc	47000pF±5%	7.5×8.0	4.0	5.0	B1	E1
RCE7U2J943JU H03	U2J (EIA)	630Vdc	94000pF±5%	7.7×13.0	4.0	5.0	B1	E1
RCE7U3A100J2 H03	U2J (EIA)	1000Vdc	10pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U3A150J2 H03	U2J (EIA)	1000Vdc	15pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U3A220J2 H03	U2J (EIA)	1000Vdc	22pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U3A330J2 H03	U2J (EIA)	1000Vdc	33pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U3A470J2 H03	U2J (EIA)	1000Vdc	47pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U3A680J2 H03	U2J (EIA)	1000Vdc	68pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U3A101J2 H03	U2J (EIA)	1000Vdc	100pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U3A151J2 H03	U2J (EIA)	1000Vdc	150pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U3A221J2 H03	U2J (EIA)	1000Vdc	220pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U3A331J2 H03	U2J (EIA)	1000Vdc	330pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U3A471J2 H03	U2J (EIA)	1000Vdc	470pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U3A681J2 H03	U2J (EIA)	1000Vdc	680pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U3A102J2 H03	U2J (EIA)	1000Vdc	1000pF±5%	5.5×4.0	3.15	5.0	K1	M1
RCE7U3A152J3 H03	U2J (EIA)	1000Vdc	1500pF±5%	5.5×5.0	4.0	5.0	K1	M1
RCE7U3A222J3 H03	U2J (EIA)	1000Vdc	2200pF±5%	5.5×5.0	4.0	5.0	K1	M1
RCE7U3A332J4□□H03□	U2J (EIA)	1000Vdc	3300pF±5%	7.5×5.5	4.0	5.0	K1	M1
RCE7U3A472J4□□H03□	U2J (EIA)	1000Vdc	4700pF±5%	7.5×5.5	4.0	5.0	K1	M1
RCE7U3A682J5□□H03□	U2J (EIA)	1000Vdc	6800pF±5%	7.5×8.0	4.0	5.0	B1	E1
RCE7U3A103J5□□H03□	U2J (EIA)	1000Vdc	10000pF±5%	7.5×8.0	4.0	5.0	B1	E1
RCE7U3A203JU□□H03□	U2J (EIA)	1000Vdc	20000pF±5%	7.7×13.0	4.0	5.0	B1	E1

Two blank columns are filled with the lead style code. Please refer to the 3 columns on the right for the appropriate code.

The last blank column is filled with the packaging code. (B: bulk, A: ammo pack)

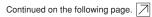


High Dielectric Constant Type, X7R/X7S Characteristics

Part Number	Temp.	Rated	Capacitance	Dimensions LxW	Dimension T	Lead Space F	Lead Style Code	Lead Style Code
DOEDT FOOTIVO TO LICOT	Char.	Voltage	0.0 5.100/	(mm)	(mm)	(mm)	Bulk	Taping
RCER71E335K2 H03	X7R (EIA)	25Vdc	3.3µF±10%	5.5×4.0	3.15	2.5	A2	DB
RCER71E335K2 H03	X7R (EIA)	25Vdc	3.3µF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER71E475K2 H03	X7R (EIA)	25Vdc	4.7μF±10%	5.5×4.0	3.15	2.5	A2	DB
RCER71E475K2 H03	X7R (EIA)	25Vdc	4.7μF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER71E106K3 H03	X7R (EIA)	25Vdc	10μF±10%	5.5×5.0	4.0	2.5	A2	DB
RCER71E106K3 H03	X7R (EIA)	25Vdc	10µF±10%	5.5×5.0	4.0	5.0	K1	M1
RCER71E226MW□□H03□	X7R (EIA)	25Vdc	22µF±20%	5.5×7.5	4.0	5.0	K1	M1
RCER71H221K0□□H03□	X7R (EIA)	50Vdc	220pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H221K0 - H03	X7R (EIA)	50Vdc	220pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H331K0 H03	X7R (EIA)	50Vdc	330pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H331K0 - H03	X7R (EIA)	50Vdc	330pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H471K0 - H03	X7R (EIA)	50Vdc	470pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H471K0 - H03	X7R (EIA)	50Vdc	470pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H681K0□□H03□	X7R (EIA)	50Vdc	680pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H681K0 H03	X7R (EIA)	50Vdc	680pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H102K0 H03	X7R (EIA)	50Vdc	1000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H102K0 - H03	X7R (EIA)	50Vdc	1000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H152K0 - H03	X7R (EIA)	50Vdc	1500pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H152K0□□H03□	X7R (EIA)	50Vdc	1500pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H222K0□□H03□	X7R (EIA)	50Vdc	2200pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H222K0□□H03□	X7R (EIA)	50Vdc	2200pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H332K0□□H03□	X7R (EIA)	50Vdc	3300pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H332K0□□H03□	X7R (EIA)	50Vdc	3300pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H472K0□□H03□	X7R (EIA)	50Vdc	4700pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H472K0□□H03□	X7R (EIA)	50Vdc	4700pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H682K0□□H03□	X7R (EIA)	50Vdc	6800pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H682K0□□H03□	X7R (EIA)	50Vdc	6800pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H103K0□□H03□	X7R (EIA)	50Vdc	10000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H103K0□□H03□	X7R (EIA)	50Vdc	10000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H153K0□□H03□	X7R (EIA)	50Vdc	15000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H153K0□□H03□	X7R (EIA)	50Vdc	15000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H223K0□□H03□	X7R (EIA)	50Vdc	22000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H223K0□□H03□	X7R (EIA)	50Vdc	22000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H333K0□□H03□	X7R (EIA)	50Vdc	33000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H333K0□□H03□	X7R (EIA)	50Vdc	33000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H473K0□□H03□	X7R (EIA)	50Vdc	47000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H473K0□□H03□	X7R (EIA)	50Vdc	47000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H683K0□□H03□	X7R (EIA)	50Vdc	68000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H683K0□□H03□	X7R (EIA)	50Vdc	68000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H104K0□□H03□	X7R (EIA)	50Vdc	0.10µF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER71H104K0□□H03□	X7R (EIA)	50Vdc	0.10µF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER71H154K1□□H03□	X7R (EIA)	50Vdc	0.15μF±10%	4.0×3.5	2.5	2.5	A2	DB
RCER71H154K1□□H03□	X7R (EIA)	50Vdc	0.15μF±10%	4.0×3.5	2.5	5.0	K1	M1
RCER71H224K1□□H03□	X7R (EIA)	50Vdc	0.22μF±10%	4.0×3.5	2.5	2.5	A2	DB
RCER71H224K1□□H03□	X7R (EIA)	50Vdc	0.22μF±10%	4.0×3.5	2.5	5.0	K1	M1
RCER71H334K1□□H03□	X7R (EIA)	50Vdc	0.33µF±10%	4.0×3.5	2.5	2.5	A2	DB
RCER71H334K1□□H03□	X7R (EIA)	50Vdc	0.33µF±10%	4.0×3.5	2.5	5.0	K1	M1
RCER71H474K1□□H03□	X7R (EIA)	50Vdc	0.47μF±10%	4.0×3.5	2.5	2.5	A2	DB
RCER71H474K1□□H03□	X7R (EIA)	50Vdc	0.47μF±10%	4.0×3.5	2.5	5.0	K1	M1
RCER71H684K2□□H03□	X7R (EIA)	50Vdc	0.68µF±10%	5.5×4.0	3.15	2.5	A2	DB
RCER71H684K2□□H03□	X7R (EIA)	50Vdc	0.68µF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER71H105K2□□H03□	X7R (EIA)	50Vdc	1.0µF±10%	5.5×4.0	3.15	2.5	A2	DB
RCER71H105K2□□H03□	X7R (EIA)	50Vdc	1.0µF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER71H155K2□□H03□	X7R (EIA)	50Vdc	1.5µF±10%	5.5×4.0	3.15	2.5	A2	DB
RCER71H155K2□□H03□	X7R (EIA)	50Vdc	1.5µF±10%	5.5×4.0	3.15	5.0	K1	M1

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RCER71H225K2□□H03□	X7R (EIA)	50Vdc	2.2µF±10%	5.5×4.0	3.15	2.5	A2	DB
RCER71H225K2□□H03□	X7R (EIA)	50Vdc	2.2µF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER71H335K3□□H03□	X7R (EIA)	50Vdc	3.3µF±10%	5.5×5.0	4.0	2.5	A2	DB
RCER71H335K3□□H03□	X7R (EIA)	50Vdc	3.3µF±10%	5.5×5.0	4.0	5.0	K1	M1
RCER71H475K3□□H03□	X7R (EIA)	50Vdc	4.7μF±10%	5.5×5.0	4.0	2.5	A2	DB
RCER71H475K3□□H03□	X7R (EIA)	50Vdc	4.7μF±10%	5.5×5.0	4.0	5.0	K1	M1
RCER71H106MW□□H03□	X7R (EIA)	50Vdc	10µF±20%	5.5×7.5	4.0	5.0	K1	M1
RCER72A221K0□□H03□	X7R (EIA)	100Vdc	220pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER72A221K0□□H03□	X7R (EIA)	100Vdc	220pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER72A331K0□□H03□	X7R (EIA)	100Vdc	330pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER72A331K0□□H03□	X7R (EIA)	100Vdc	330pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER72A471K0□□H03□	X7R (EIA)	100Vdc	470pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER72A471K0□□H03□	X7R (EIA)	100Vdc	470pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER72A681K0□□H03□	X7R (EIA)	100Vdc	680pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER72A681K0□□H03□	X7R (EIA)	100Vdc	680pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER72A102K0□□H03□	X7R (EIA)	100Vdc	1000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER72A102K0□□H03□	X7R (EIA)	100Vdc	1000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER72A152K0□□H03□	X7R (EIA)	100Vdc	1500pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER72A152K0□□H03□	X7R (EIA)	100Vdc	1500pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER72A222K0□□H03□	X7R (EIA)	100Vdc	2200pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER72A222K0□□H03□	X7R (EIA)	100Vdc	2200pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER72A332K0□□H03□	X7R (EIA)	100Vdc	3300pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER72A332K0□□H03□	X7R (EIA)	100Vdc	3300pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER72A472K0□□H03□	X7R (EIA)	100Vdc	4700pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER72A472K0□□H03□	X7R (EIA)	100Vdc	4700pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER72A682K0□□H03□	X7R (EIA)	100Vdc	6800pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER72A682K0□□H03□	X7R (EIA)	100Vdc	6800pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER72A103K0□□H03□	X7R (EIA)	100Vdc	10000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER72A103K0□□H03□	X7R (EIA)	100Vdc	10000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER72A153K0 H03	X7R (EIA)	100Vdc	15000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER72A153K0 H03	X7R (EIA)	100Vdc	15000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER72A223K0 H03	X7R (EIA)	100Vdc	22000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RCER72A223K0 H03	X7R (EIA)	100Vdc	22000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RCER72A333K1 H03	X7R (EIA)	100Vdc	33000pF±10%	4.0×3.5	2.5	2.5	A2	DB
RCER72A333K1 H03	X7R (EIA)	100Vdc	33000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RCER72A473K1 H03	X7R (EIA)	100Vdc	47000pF±10%	4.0×3.5	2.5	2.5	A2	DB
RCER72A473K1 H03	X7R (EIA)	100Vdc	47000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RCER72A683K1 H03	X7R (EIA)	100Vdc	68000pF±10%	4.0×3.5	2.5	2.5	A2	DB
RCER72A683K1□□H03□ RCER72A104K1□□H03□	X7R (EIA)	100Vdc 100Vdc	68000pF±10%	4.0×3.5	2.5	5.0 2.5	K1 A2	M1 DB
RCER72A104K1 H03H03H	X7R (EIA) X7R (EIA)	100Vdc	0.10μF±10% 0.10μF±10%	4.0×3.5 4.0×3.5	2.5	5.0	K1	M1
RCER72A104K1 H03 RCER72A154K2 H03	X7R (EIA)	100Vdc	0.10μF±10% 0.15μF±10%	5.5×4.0	3.15	2.5	A2	DB
RCER72A154K2 H03	X7R (EIA)	100Vdc	0.15μF±10% 0.15μF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72A224K2 H03	X7R (EIA)	100Vdc	0.13μ1±10% 0.22μF±10%	5.5×4.0	3.15	2.5	A2	DB
RCER72A224K2 H03	X7R (EIA)	100Vdc	0.22μΓ±10% 0.22μF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72A334K1 - H03	X7R (EIA)	100Vdc	0.22μΓ±10% 0.33μF±10%	4.0×3.5	2.5	2.5	A2	DB
RCER72A334K1 - H03	X7R (EIA)	100Vdc	0.33µF±10%	4.0×3.5	2.5	5.0	K1	M1
RCER72A474K2 H03	X7R (EIA)	100Vdc	0.47μF±10%	5.5×4.0	3.15	2.5	A2	DB
RCER72A474K2 H03	X7R (EIA)	100Vdc	0.47μF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72A684K2 H03	X7R (EIA)	100Vdc	0.68µF±10%	5.5×4.0	3.15	2.5	A2	DB
RCER72A684K2□□H03□	X7R (EIA)	100Vdc	0.68µF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72A105K2□□H03□	X7R (EIA)	100Vdc	1.0µF±10%	5.5×4.0	3.15	2.5	A2	DB
RCER72A105K2□□H03□	X7R (EIA)	100Vdc	1.0µF±10%	5.5×4.0	3.15	5.0	K1	M1
RCEC72A155K3□□H03□	X7S (EIA)	100Vdc	1.5µF±10%	5.5×5.0	4.0	2.5	A2	DB
RCEC72A155K3□□H03□	X7S (EIA)	100Vdc	1.5µF±10%	5.5×5.0	4.0	5.0	K1	M1
RCEC72A225K3□□H03□	X7S (EIA)	100Vdc	2.2µF±10%	5.5×5.0	4.0	2.5	A2	DB
RCEC72A225K3□□H03□	X7S (EIA)	100Vdc	2.2µF±10%	5.5×5.0	4.0	5.0	K1	M1
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Continued from the preceding page.

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RCEC72A475MW□□H03□	X7S (EIA)	100Vdc	4.7μF±20%	5.5×7.5	4.0	5.0	K1	M1
RCER72E102K1□□H03□	X7R (EIA)	250Vdc	1000pF±10%	4.0×3.5	3.15	5.0	K1	M1
RCER72E152K1□□H03□	X7R (EIA)	250Vdc	1500pF±10%	4.0×3.5	3.15	5.0	K1	M1
RCER72E222K1□□H03□	X7R (EIA)	250Vdc	2200pF±10%	4.0×3.5	3.15	5.0	K1	M1
RCER72E332K1□□H03□	X7R (EIA)	250Vdc	3300pF±10%	4.0×3.5	3.15	5.0	K1	M1
RCER72E472K1□□H03□	X7R (EIA)	250Vdc	4700pF±10%	4.0×3.5	3.15	5.0	K1	M1
RCER72E682K1□□H03□	X7R (EIA)	250Vdc	6800pF±10%	4.0×3.5	3.15	5.0	K1	M1
RCER72E103K1□□H03□	X7R (EIA)	250Vdc	10000pF±10%	4.0×3.5	3.15	5.0	K1	M1
RCER72E153K1□□H03□	X7R (EIA)	250Vdc	15000pF±10%	4.0×3.5	3.15	5.0	K1	M1
RCER72E223K1□□H03□	X7R (EIA)	250Vdc	22000pF±10%	4.0×3.5	3.15	5.0	K1	M1
RCER72E333K2□□H03□	X7R (EIA)	250Vdc	33000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72E473K2□□H03□	X7R (EIA)	250Vdc	47000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72E683K2□□H03□	X7R (EIA)	250Vdc	68000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72E104K2□□H03□	X7R (EIA)	250Vdc	0.10µF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72E154K3□□H03□	X7R (EIA)	250Vdc	0.15µF±10%	5.5×5.0	4.0	5.0	K1	M1
RCER72E224K3□□H03□	X7R (EIA)	250Vdc	0.22µF±10%	5.5×5.0	4.0	5.0	K1	M1
RCER72E334K4□□H03□	X7R (EIA)	250Vdc	0.33µF±10%	7.5×5.5	4.0	5.0	K1	M1
RCER72E474K4□□H03□	X7R (EIA)	250Vdc	0.47µF±10%	7.5×5.5	4.0	5.0	K1	M1
RCER72E684K5□□H03□	X7R (EIA)	250Vdc	0.68µF±10%	7.5×7.5	4.0	5.0	B1	E1
RCER72E105K5 H03	X7R (EIA)	250Vdc	1.0µF±10%	7.5×7.5	4.0	5.0	B1	E1
RCER72E225MU H03	X7R (EIA)	250Vdc	2.2µF±20%	7.5×12.5	4.0	5.0	B1	E1
RCER72J102K2 H03	X7R (EIA)	630Vdc	1000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72J152K2 H03	X7R (EIA)	630Vdc	1500pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72J222K2 H03	X7R (EIA)	630Vdc	2200pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72J332K2 H03	X7R (EIA)	630Vdc	3300pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72J472K2 H03	X7R (EIA)	630Vdc	4700pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72J682K2 H03	X7R (EIA)	630Vdc	6800pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72J103K2 H03	X7R (EIA)	630Vdc	10000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72J153K2 - H03	X7R (EIA)	630Vdc	15000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72J223K2 H03	X7R (EIA)	630Vdc	22000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER72J333K3 H03	X7R (EIA)	630Vdc	33000pF±10%	5.5×5.0	4.0	5.0	K1	M1
RCER72J473K3 H03	X7R (EIA)	630Vdc	47000pF±10%	5.5×5.0	4.0	5.0	K1	M1
RCER72J683K4 H03	X7R (EIA)	630Vdc	68000pF±10%	7.5×5.5				
RCER72J104K4 H03		630Vdc		7.5×5.5	4.0	5.0	K1	M1 M1
RCER72J154K5 H03	X7R (EIA)	630Vdc	0.10µF±10%	7.5×8.0	4.0	5.0	B1	E1
RCER72J224K5 H03	X7R (EIA)	630Vdc	0.15µF±10% 0.22µF±10%	7.5×8.0	4.0	5.0	B1	E1
RCER72J474MU H03								
	X7R (EIA)	630Vdc	0.47μF±20%	7.7×13.0	4.0	5.0	B1	E1
RCER73A102K2 H03	X7R (EIA)	1000Vdc	1000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER73A152K2 H03	X7R (EIA)	1000Vdc	1500pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER73A222K2 H03	X7R (EIA)	1000Vdc	2200pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER73A332K2 H03	X7R (EIA)	1000Vdc	3300pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER73A472K2 H03	X7R (EIA)	1000Vdc	4700pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER73A682K2 H03	X7R (EIA)	1000Vdc	6800pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER73A103K2 H03	X7R (EIA)	1000Vdc	10000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RCER73A153K3 H03	X7R (EIA)	1000Vdc	15000pF±10%	5.5×5.0	4.0	5.0	K1	M1
RCER73A223K3 H03	X7R (EIA)	1000Vdc	22000pF±10%	5.5×5.0	4.0	5.0	K1	M1
RCER73A333K4 H03	X7R (EIA)	1000Vdc	33000pF±10%	7.5×5.5	4.0	5.0	K1	M1
RCER73A473K4 H03	X7R (EIA)	1000Vdc	47000pF±10%	7.5×5.5	4.0	5.0	K1	M1
RCER73A683K5□□H03□	X7R (EIA)	1000Vdc	68000pF±10%	7.5×8.0	4.0	5.0	B1	E1
RCER73A104K5□□H03□	X7R (EIA)	1000Vdc	0.10µF±10%	7.5×8.0	4.0	5.0	B1	E1
RCER73A224MU□□H03□	X7R (EIA)	1000Vdc	0.22µF±20%	7.7×13.0	4.0	5.0	B1	E1

Two blank columns are filled with the lead style code. Please refer to the 3 columns on the right for the appropriate code.

The last blank column is filled with the packaging code. (B: bulk, A: ammo pack)



Temperature Compensating Type Specifications and Test Methods

No.	AEC-Q200	Test Item	Specifications	AEC-Q200 Test Method
1	Pre-and P	ost-Stress Test		-
	High Tem Exposure	•	The measured and observed characteristics should satisfy the specifications in the following table.	
		Appearance	No defects or abnormalities	
		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	Sit the capacitor for 1,000±12h at 150±3°C. Let sit for 24±2h at
2		Q	$30pF \le C$: Q ≥ 350 $10pF \le C < 30pF$: Q ≥ 275+5C/2 10pF > C: Q ≥ 200+10C C: Nominal Capacitance (pF)	room temperature, then measure.
		I.R.	More than 1,000MΩ or 50MΩ·μF (Whichever is smaller)	-
	Temperat Cycling		The measured and observed characteristics should satisfy the specifications in the following table.	
		Appearance	No defects or abnormalities	Perform the 1,000 cycles according to the four heat treatments
		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	listed in the following table. Let sit for 24±2h at *room condition, then measure.
3		Q	$30pF \le C: Q \ge 350$ $10pF \le C < 30pF: Q \ge 275+5C/2$ $10pF > C: Q \ge 200+10C$	Step 1 2 3 4 Temp. (°C) -55+0/-3 Room Temp. 125+3/-0 Room Temp. Time (min.) 15±3 1 15±3 1
			C: Nominal Capacitance (pF)	_
		I.R.	1,000M Ω or 50M Ω · μF min. (Whichever is smaller)	
	Moisture Resistance		The measured and observed characteristics should satisfy the specifications in the following table.	Apply the 24h heat (25 to 65°C) and humidity (80 to 98%) treatment shown below, 10 consecutive times. Let sit for 24±2h at *room condition, then measure.
		Appearance	No defects or abnormalities	Humidity Humidity Humidity Humidity Humidity
		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	(°C) 90-98% 80-98% 90-98% 80-98% 90-98% 70 65 60 70 70 70 70 70 70 70 70 70 70 70 70 70
4		Q	$30pF \le C: Q \ge 200$ $30pF > C: Q \ge 100+10C/3$	55 50 45 45 40 87 35
		I.R.	C: Nominal Capacitance (pF) $500M\Omega \text{ or } 25M\Omega \cdot \mu\text{F min. (Whichever is smaller)}$	0 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 Hours
	Biased Hu	umidity	The measured and observed characteristics should satisfy the specifications in the following table.	
		Appearance	No defects or abnormalities	
5		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	Apply the rated voltage and DC1.3+0.2/-0V (add 6.8kΩ resistor) at 85±3°C and 80 to 85% humidity for 1,000±12h. Remove and let sit for 24±2h at *room condition, then measure.
		Q	$30pF \le C: Q \ge 200$ $30pF > C: Q \ge 100+10C/3$	The charge/discharge current is less than 50mA.
			C: Nominal Capacitance (pF)	
		I.R.	500MΩ or 25MΩ · μF min. (Whichever is smaller)	
	Operation	al Life	The measured and observed characteristics should satisfy the specifications in the following table.	
		Appearance	No defects or abnormalities	Apply the voltage shown in the table for 1,000±12h at 125±3°C.
		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	Let sit for 24±2h at *room condition, then measure. The charge/discharge current is less than 50mA.
6	Q		$30pF \le C: Q \ge 350$ $10pF \le C < 30pF: Q \ge 275+5C/2$ $10pF > C: Q \ge 200+10C$	Rated VoltageTest VoltageDC50V, DC100V200% of the rated voltageDC250V150% of the rated voltageDC630V, DC1kV120% of the rated voltage
			C: Nominal Capacitance (pF)	_
		I.R.	1,000M Ω or 50M Ω · μF min. (Whichever is smaller)	

 $^{^{\}star}$ "room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmosphere pressure: 86 to 106kPa



Temperature Compensating Type Specifications and Test Methods

 $\begin{tabular}{|c|c|c|c|}\hline \end{tabular}$ Continued from the preceding page.

No.	AEC-Q200	Test Item	Specifications	AEC-Q200 Test Method				
7	External V	/isual	No defects or abnormalities	Visual inspection				
8	Physical [Dimension	Within the specified dimensions	Using calipers and micrometers.				
9	Marking		To be easily legible.	Visual inspection				
		Appearance	No defects or abnormalities	Per MIL-STD-202 Method 215				
		Capacitance	Within the specified tolerance	Solvent 1: 1 part (by volume) of isopropyl alcohol				
10	Resistance to Solvents	Q	30pF ≤ C: Q ≥ 1,000 30pF > C: Q ≥ 400+20C	3 parts (by volume) of mineral spirits Solvent 2: Terpene defluxer Solvent 3: 42 parts (by volume) of water				
			C: Nominal Capacitance (pF)	1 part (by volume) of propylene glycol monomethyl ether				
		I.R.	More than 10,000M Ω or 500M $\Omega \cdot \mu F$ (Whichever is smaller)	1 part (by volume) of monoethanolamine				
		Appearance	No defects or abnormalities					
		Capacitance	Within the specified tolerance	Three shocks in each direction should be applied along 3 mutually perpendicular axes of the test specimen (18 shocks)				
11	Mechanical Shock	Q	30pF ≤ C : Q ≥ 1,000 30pF > C : Q ≥ 400+20C	The specified test pulse should be Half-sine and should have a duration: 0.5ms, peak value: 1,500G and velocity change: 4.7m/s.				
			C : Nominal Capacitance (pF)	Granger mine.				
		Appearance	No defects or abnormalities	The capacitor should be subjected to a simple harmonic motion				
		Capacitance	Within the specified tolerance	having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 2,000Hz.				
12	Vibration	Q	30pF ≤ C: Q ≥ 1,000 30pF > C: Q ≥ 400+20C	The frequency range, from 10 to 2,000Hz and return to 10H should be traversed in approximately 20min. This motion should be applied for 12 items in each 3 mutually perpendic				
			C: Nominal Capacitance (pF)	directions (total of 36 times).				
	Resistance Soldering I		The measured and observed characteristics should satisfy the specifications in the following table.					
		Appearance	No defects or abnormalities					
13		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	The lead wire is immersed in the melted solder 1.5 to 2mm from the main body at 260±5°C for 10±1s. The specified items are measured after 24±2h.				
		Dielectric Strength (Between Terminals)	No defects					
	Thermal S	Shock	The measured and observed characteristics should satisfy the specifications in the following table.	Perform the 300 cycles according to the two heat treatments				
		Appearance	No defects or abnormalities					
14		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	listed in the following table (Maximum transfer time is 20s.). Let sit for 24±2h at *room condition, then measure.				
1-7		Q	$30pF \le C: Q \ge 350$ $10pF \le C < 30p: Q \ge 275+5C/2$ $10pF > C: Q \ge 200+10C$	Step 1 2 Temp. (°C) -55+0/-3 125+3/-0 Time (min.) 15±3 15±3				
			C: Nominal Capacitance (pF)					
		I.R.	1,000M Ω or 50M Ω · μ F min. (Whichever is smaller)					
		Appearance	No defects or abnormalities					
		Capacitance	Within the specified tolerance	_				
15	ESD	Q	$30pF \le C: Q \ge 1,000$ $30pF > C: Q \ge 400+20C$	Per AEC-Q200-004				
			C: Nominal Capacitance (pF)					
		I.R.	More than 10,000M Ω or 500M $\Omega \cdot \mu F$ (Whichever is smaller)					
16	Solderabi	lity	Lead wire should be soldered with uniform coating on the axial direction over 95% of the circumferential direction.	Should be placed into steam aging for 8h±15min. The terminal of capacitor is dipped into a solution of ethanol (JIS K 8101) and rosin (JIS K 5902) (25% rosin in weight propotion). Immerse in solder solution for 2±0.5 seconds. In both cases the depth of dipping is up to about 1.5 to 2mm from the terminal body.				

 $^{^{\}star}$ "room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmosphere pressure: 86 to 106kPa





Temperature Compensating Type Specifications and Test Methods

Continued from the preceding page.

No.	AEC-Q200	Test Item	Specif	fications	AEC	C-Q200 Test Mo	ethod	
		Appearance	No defects or abnormalities		Visual inspection.			
		Capacitance	Within the specified tolerance 30pF ≤ C: Q ≥ 1,000		The capacitance, Q sho frequency and voltage			
		Q	$30pF > C: Q \ge 400+20C$ C: Nominal Capacitance (pF)		Nominal Cap. C ≤ 1000pF C > 1000pF	Frequency 1±0.1MHz 1±0.1kHz	Voltage AC0.5 to 5V (r.m.s.) AC1±0.2V (r.m.s.)	
		I.R.	Between Terminals	10,000MΩ or 500MΩ \cdot μF min. (Whichever is smaller)	The insulation resistand voltage not exceeding to f charging.			
17	Electrical Charac- terization				The capacitor should no shown in the table is ap for 1 to 5 seconds. (Charge/Discharge curr	plied between t		
			Between Terminals	No defects or abnormalities		Rated Voltage Test Voltage DC50V, DC100V 300% of the rated voltage		
	Dielectric Strength							
					DC250V DC630V		of the rated voltage of the rated voltage	
					DC1kV		of the rated voltage	
			Body Insulation	No defects or abnormalities	The capacitor is placed in a container with metal balls of 1mm diameter so that each terminal, short-circuit is kept approximately 2mm from the balls, and 250% of the rated DC voltage is impressed for 1 to 5 seconds between capacitor terminals and metal balls. (Charge/Discharge current ≤ 50mA.) As in the figure, fix the capacitor body, apply the force			
18	Terminal Strength	Tensile Strength	Termination not to be broken o	r loosened	As in the figure, fix the gradually to each lead i until reaching 10N and 10±1 seconds.	n the radial dire	ction of the capacitor	
		Bending Strength	Termination not to be broken o	r loosened	Each lead wire should be subjected to a force of 2.5N and there is be bent 90° at the point of egress in one direction. Each wire is then returned to the original position and bent 90° in the opposite direction at the rate of one bend per 2 to 3 seconds.			
					The capacitance chang each specified tempera		asured after 5min. at	
					Step	1	Temperature (°C)	
					1		25±2	
					2		-55±3	
			Within the specified Tolerance.		3		25±2	
	Capacitar	nce	(Table A)		<u>4</u> 5		125±3 25±2	
19	•		Capacitance Drift is within ±0.2 (Whichever is larger)	The temperature coefficient is determind using the capacitant measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5 (-55°C to +125°C) the capacitance should be within the specified tolerance for the temperature coefficient and capacitance change as Table A. The capacitance drift is caluculated by dividing the differences between the maximum and minimum measured values in the				

^{* &}quot;room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmosphere pressure: 86 to 106kPa

Table A

Ī		Nominal Values	С	Capacitance Change from 25°C (%)							
	Char.	(ppm/°C) *	-5	55	-3	30	-10				
		(ppiii/ C)	Max.	Min.	Max.	Min.	Max.	Min.			
	C0G	0±30	0.58	-0.24	0.40	-0.17	0.25	-0.11			
	U2J	-750±120	8.78	5.04	6.04	3.47	3.84	2.21			

^{*} Nominal values denote the temperature coefficient within a range of 25°C to 125°C.



High Dielectric Constant Type Specifications and Test Methods

No.	AEC-Q200	Test Item	Specifications	AEC-Q200 1	Test Method		
1	Pre-and P	ost-Stress Test		_			
	High Tem Exposure	perature (Storage)	The measured and observed characteristics should satisfy the specifications in the following table.				
		Appearance	No defects or abnormalities	0::1			
2		Capacitance Change	Within ±12.5%	Sit the capacitor for 1,000±12h room temperature, then measur			
		D.F.	0.04 max.				
		I.R.	More than 1,000M Ω or $50M\Omega \cdot \mu F$ (Whichever is smaller)				
	Temperat Cycling	ture	The measured and observed characteristics should satisfy the specifications in the following table.	Perform the 1,000 cycles accordisted in the following table. Let	_		
		Appearance	No defects or abnormalities	then measure.			
3		Capacitance Change	Within ±12.5%	Step 1 2 Temp. (°C) -55+0/-3 Room Time (min.) 15±3 1	Temp. 125+3/-0 Room Temp.		
		D.F.	0.05 max.	•Pretreatment			
		I.R.	1,000MΩ or 50MΩ · μF min. (Whichever is smaller)	Perform the heat treatment at then let sit for 24±2h at *room			
	Moisture Resistance		The measured and observed characteristics should satisfy the specifications in the following table.	Apply the 24h heat (25 to 65°C) treatment shown below, 10 cons	secutive times.		
			No defects or abnormalities	Let sit for 24±2h at *room condi	,		
		Capacitance Change	Within ±12.5%	Humidity Humidity Humidity Humidity Humidity (°C) 90-98% 80-98% 90-98% 80-98% 90-98% 70 65 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4			
		D.F.	0.05 max.	55 50			
4		I.R.	500MΩ or 25MΩ · μF min. (Whichever is smaller)	0 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22 23 24 Hours			
	Biased H	umidity	The measured and observed characteristics should satisfy the specifications in the following table.				
		Appearance	No defects or abnormalities		1.3+0.2/-0V (add 6.8kΩ resistor)		
5		Capacitance Change	Within ±12.5%	at 85±3°C and 80 to 85% humic Remove and let sit for 24±2h at The charge/discharge current is	*room condition, then measure.		
		D.F.	0.05 max.				
		I.R.	$500 M\Omega$ or $25 M\Omega \cdot \mu \text{F}$ min. (Whichever is smaller)				
	Operation	nal Life	The measured and observed characteristics should satisfy the specifications in the following table.	Let sit for 24±2h at *room condi			
		Appearance	No defects or abnormalities	The charge/discharge current is •Pretreatment	iess than duma.		
6		Capacitance Change	Within ±12.5%	Apply test voltage for 60±5min Remove and let sit for 24±2h a			
		D.F.	0.04 max.	Rated Voltage	Test Voltage		
		I.R.	1,000Μ Ω or 50Μ $\Omega \cdot \mu$ F min. (Whichever is smaller)	DC25V, DC50V, DC100V DC250V DC630V DC1kV	200% of the rated voltage *1 150% of the rated voltage 120% of the rated voltage 110% of the rated voltage		
7	External \	/isual	No defects or abnormalities	Visual inspection			
8	Physical I	Dimension	Within the specified dimensions	Using calipers and micrometers			
9			To be easily legible.	Visual inspection			
	Marking		To be easily legible.				

^{* &}quot;room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmosphere pressure: 86 to 106kPa

^{*1:} below parts are applicable in rated voltage×150%.

			-		
Ch	ar.	Rated Voltage	Capacitance	Dimensions	
R	7	2A	334	1	
R	7	2A	474-105	2	
С	7	2A	155-225	3	
С	7	2A	475	W	



High Dielectric Constant Type Specifications and Test Methods

() Continued from the preceding page.

lo.	AEC-Q200	Test Item	Specifications		AEC-Q200 Test M	lethod		
		Appearance	No defects or abnormalities	Per MIL-STD-202	Method 215			
		Capacitance	Within the specified tolerance		t (by volume) of isop ts (by volume) of mir			
0	Resistance	D.F.	0.025 max.	Solvent 2: Terpe	· •	ierai spirits		
U	to Solvents	I.R.	More than 10,000M Ω or 500M $\Omega \cdot \mu F$ (Whichever is smaller)	1 par mond	arts (by volume) of wa t (by volume) of propo omethyl ether t (by volume) of mon	ylene glycol		
		Appearance	No defects or abnormalities		each direction should			
1	Mechanical	Capacitance	Within the specified tolerance		ndicular axes of the to t pulse should be Ha	est specimen (18 shocks lf-sine and should		
	Shock	D.F.	0.025 max.).5ms, peak value: 1			
		Appearance	No defects or abnormalities		•	a simple harmonic motion		
		Capacitance	Within the specified tolerance			e frequency being varied nits of 10 and 2,000Hz.		
2	Vibration	D.F.	0.025 max.	The frequency range, from 10 to 2,000Hz and return to 10Hz, should be traversed in approximately 20min. This motion should be applied for 12 items in each 3 mutually perpendicular directions (total of 36 times).				
			The measured and observed characteristics should satisfy the specifications in the following table.					
		Appearance	No defects or abnormalities			ed solder 1.5 to 2mm		
3		Capacitance Change	Wthin ±7.5%	are measured after	•	±1s. The specified items		
		Dielectric Strength (Between terminals)	No defects	Perform the heat treatment at 150+0/-10°C for 60±5min and then let sit for 24±2h at *room condition.				
	Thermal S	Shock	The measured and observed characteristics should satisfy the specifications in the following table.	Perform the 300 cycles according to the two heat treatments listed in the following table (Maximum transfer time is 20s.).				
		Appearance	No defects or abnormalities	Let sit for 24±2h a	at *room condition, th	nen measure.		
4		Capacitance	Within ±12.5%	Step	1	2 125+3/-0		
٦		Change	WIGHIN ±12.376	Temp. (°C) Time (min.)	-55+0/-3 15±3	15±3		
		D.F.	0.05 max.	•Pretreatment				
		I.R.	1,000M Ω or $50M\Omega \cdot \mu F$ min. (Whichever is smaller)		t treatment at 150+0. L±2h at *room conditi	/-10°C for 60±5min and ion.		
		Appearance	No defects or abnormalities					
5	ESD	Capacitance	Within the specified tolerance	Por AEC 0200 0	24			
٦	LOD	D.F.	0.025 max.	Per AEC-Q200-004				
		I.R.	More than 10,000M Ω or $500M\Omega \cdot \mu F$ (Whichever is smaller)					
6 Solderability		lity	Lead wire should be soldered with uniform coating on the axial direction over 95% of the circumferential direction.	Should be placed into steam aging for 8h±15min. The terminal of capacitor is dipped into a solution of ethanol (JIS K 8101) and rosin (JIS K 5902) (25% rosin in weight propotion). Immerse in solder solution for 2±0.5 seconds. In both cases the depth of dipping is up to about 1.5 to 2mm from the terminal body.				

^{* &}quot;room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmosphere pressure: 86 to 106kPa





High Dielectric Constant Type Specifications and Test Methods

Continued from the preceding page.

lo. AEC-Q20	0 Test Item	Specif	ications	AEC-Q200	Test Method	
	Appearance	No defects or abnormalities		Visual inspection.		
	Capacitance	Within the specified tolerance		The capacitance/D.F. should be frequency and voltage shown in		
	D.F.	0.025 max.		Frequency 1±0.1kHz	Voltage 1±0.2V (r.m.s.)	
	I.R.	Between Terminals	10,000Μ Ω or 500Μ $\Omega \cdot \mu$ F min. (Whichever is smaller)	The insulation resistance shoul voltage not exceeding the rated of charging.		
Electrica				The capacitor should not be day shown in the table is applied be for 1 to 5 seconds. (Charge/Discharge current ≤ 50	etween the terminations	
terization	Dielectric Strength		No defects or abnormalities	Rated Voltage DC25V, DC50V, DC100V DC250V DC630V DC1kV	Test Voltage 250% of the rated voltage 200% of the rated voltage 150% of the rated voltage 120% of the rated voltage	
		Body Insulation	No defects or abnormalities	The capacitor is placed in a container with metal balls of 1mm diameter so that each terminal, short-circuit is kept approximately 2mm from the balls, and 250% of the rated DC voltage is impressed for 1 to 5 seconds between capacitor terminals and metal balls. (Charge/Discharge current ≤ 50mA.) As in the figure, fix the capacitor body, apply the force		
Terminal Strength		Lermination not to be broken or loosened		As in the figure, fix the capacitor gradually to each lead in the rauntil reaching 10N and then ker 10±1 seconds.	dial direction of the capacitor	
	Bending Strength	Termination not to be broken or	r loosened			
Capacita 19 Tempera Characte	ture	Char.X7R: Within ±15% Char.X7S: Within ±22%		The capacitance change should each specified temperature ste Step 1 2 3 4 5 The ranges of capacitance cha 25°C value over the temperature should be within the specified representation of	Temperature (°C) 25±2 -55±3 25±2 125±3 25±2 nge compared with the above re ranges shown in the table	

^{* &}quot;room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmosphere pressure: 86 to 106kPa



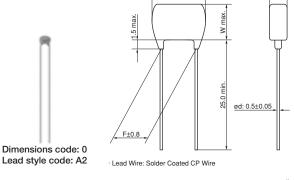
Radial Lead Type Monolithic Ceramic Capacitors



RHE Series 150°C max. (for Automotive) (DC50V-DC100V)

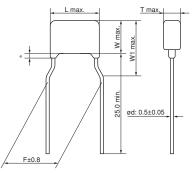
Features

- 1. Small size and large capacitance
- 2. Low ESR and ESL suitable for high frequency
- 3. Applied maximum temperature up to 150°C Note: Maximum accumulative time to 150°C is within 2000 hours.
- 4. Meet AEC-Q200, ISO7637-2 (surge test) requirement
- 5. Meet LF (Lead Free) and HF (Halogen Free)
- 6. Flow soldering and welding are available. (Re-flow soldering is not available.)
- 7. If copper wire is necessary at welding process, copper wire is available based on request.



(in mm)

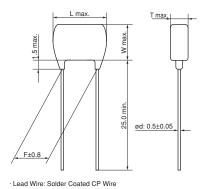




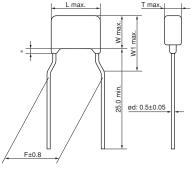
Coating extension does not exceed the end of the lead bend Lead Wire: Solder Coated CP Wire

(in mm)





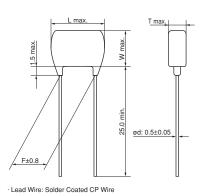




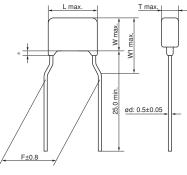
Coating extension does not exceed the end of the lead bend Lead Wire: Solder Coated CP Wire

(in mm)

Dimensions code: 2 Lead style code: A2

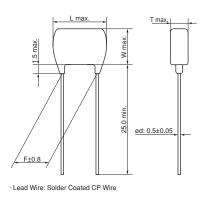






Coating extension does not exceed Lead Wire: Solder Coated CP Wire

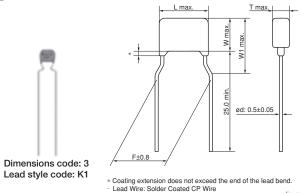
Dimensions code: 3 Lead style code: A2





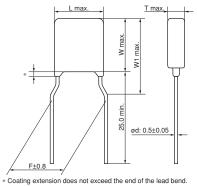


Continued from the preceding page.



(in mm)





Coating extension does not exceed the end of the lead bend. Lead Wire: Solder Coated CP Wire

■ Dimensions

Dimensions and				Dimensions (mm)		
Lead Style Code	L	W	W1	Т	F	d
0A2/0DB	3.6	3.5	-		2.5	0.5
0K1/0M1	3.6	3.5	6.0		5.0	0.5
1A2/1DB	4.0	3.5	-		2.5	0.5
1K1/1M1	4.0	3.5	5.0		5.0	0.5
2A2/2DB	5.5	4.0	-	See the individual product specification	2.5	0.5
2K1/2M1	5.5	4.0	6.0	product specimeation	5.0	0.5
3A2/3DB	5.5	5.0	-		2.5	0.5
3K1/3M1	5.5	5.0	7.5		5.0	0.5
WK1/WM1	5.5	7.5	10.0		5.0	0.5

■ Marking

Marking	Туре	Temperature Compensating Type	High Dielectric	Constant Type			
	Rated Voltage	DC50V, DC100V	DC50V	DC100V			
Dimensions Code	Temp. Char.	X8G	X	BL			
	0	8 102J	(8 104K)	(8 103K			
	1	1020	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\			
	2	_	(M 105)	(M 224 K18			
	3, W	_	(M 335 K58	_			
Temperatur	e Characteristics	Marked with code (X8G, X8L char	r.: 8)				
Nominal	I Capacitance	Marked with 3 figures					
Capacita	ince Tolerance	Marked with code					
Rate	ed Voltage	Marked with code (DC50V: 5, DC100V: 1) A part is omitted (Please refer to the marking example.)					
Manufactur	er's Identification	Marked with M A part is omitted (Please refer to the marking example.)					

Temperature Compensating Type, X8G Characteristics

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RHE5G1H101J0□□H03□	X8G (Murata)	50Vdc	100pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H101J0□□H03□	X8G (Murata)	50Vdc	100pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H121J0□□H03□	X8G (Murata)	50Vdc	120pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H121J0□□H03□	X8G (Murata)	50Vdc	120pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H151J0□□H03□	X8G (Murata)	50Vdc	150pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H151J0□□H03□	X8G (Murata)	50Vdc	150pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H181J0□□H03□	X8G (Murata)	50Vdc	180pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H181J0□□H03□	X8G (Murata)	50Vdc	180pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H221J0□□H03□	X8G (Murata)	50Vdc	220pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H221J0□□H03□	X8G (Murata)	50Vdc	220pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H271J0□□H03□	X8G (Murata)	50Vdc	270pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H271J0□□H03□	X8G (Murata)	50Vdc	270pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H331J0□□H03□	X8G (Murata)	50Vdc	330pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H331J0□□H03□	X8G (Murata)	50Vdc	330pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H391J0□□H03□	X8G (Murata)	50Vdc	390pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H391J0□□H03□	X8G (Murata)	50Vdc	390pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H471J0□□H03□	X8G (Murata)	50Vdc	470pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H471J0□□H03□	X8G (Murata)	50Vdc	470pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H561J0□□H03□	X8G (Murata)	50Vdc	560pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H561J0□□H03□	X8G (Murata)	50Vdc	560pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H681J0□□H03□	X8G (Murata)	50Vdc	680pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H681J0□□H03□	X8G (Murata)	50Vdc	680pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H821J0□□H03□	X8G (Murata)	50Vdc	820pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H821J0□□H03□	X8G (Murata)	50Vdc	820pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H102J0□□H03□	X8G (Murata)	50Vdc	1000pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H102J0 H03	X8G (Murata)	50Vdc	1000pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H122J0□□H03□	X8G (Murata)	50Vdc	1200pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H122J0□□H03□	X8G (Murata)	50Vdc	1200pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H152J0□□H03□	X8G (Murata)	50Vdc	1500pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H152J0□□H03□	X8G (Murata)	50Vdc	1500pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H182J0□□H03□	X8G (Murata)	50Vdc	1800pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H182J0□□H03□	X8G (Murata)	50Vdc	1800pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H222J0□□H03□	X8G (Murata)	50Vdc	2200pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H222J0□□H03□	X8G (Murata)	50Vdc	2200pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H272J0□□H03□	X8G (Murata)	50Vdc	2700pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H272J0□□H03□	X8G (Murata)	50Vdc	2700pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H332J0□□H03□	X8G (Murata)	50Vdc	3300pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H332J0□□H03□	X8G (Murata)	50Vdc	3300pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H392J0□□H03□	X8G (Murata)	50Vdc	3900pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G1H392J0□□H03□	X8G (Murata)	50Vdc	3900pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G1H472J1□□H03□	X8G (Murata)	50Vdc	4700pF±5%	4.0×3.5	2.5	2.5	A2	DB
RHE5G1H472J1□□H03□	X8G (Murata)	50Vdc	4700pF±5%	4.0×3.5	2.5	5.0	K1	M1
RHE5G1H562J1□□H03□	X8G (Murata)	50Vdc	5600pF±5%	4.0×3.5	2.5	2.5	A2	DB
RHE5G1H562J1□□H03□	X8G (Murata)	50Vdc	5600pF±5%	4.0×3.5	2.5	5.0	K1	M1
RHE5G1H682J1□□H03□	X8G (Murata)	50Vdc	6800pF±5%	4.0×3.5	2.5	2.5	A2	DB
RHE5G1H682J1□□H03□	X8G (Murata)	50Vdc	6800pF±5%	4.0×3.5	2.5	5.0	K1	M1
RHE5G1H822J1□□H03□	X8G (Murata)	50Vdc	8200pF±5%	4.0×3.5	2.5	2.5	A2	DB
RHE5G1H822J1□□H03□	X8G (Murata)	50Vdc	8200pF±5%	4.0×3.5	2.5	5.0	K1	M1
RHE5G1H103J1□□H03□	X8G (Murata)	50Vdc	10000pF±5%	4.0×3.5	2.5	2.5	A2	DB
RHE5G1H103J1□□H03□	X8G (Murata)	50Vdc	10000pF±5%	4.0×3.5	2.5	5.0	K1	M1
RHE5G2A101J0□□H03□	X8G (Murata)	100Vdc	100pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G2A101J0□□H03□	X8G (Murata)	100Vdc	100pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A121J0□□H03□	X8G (Murata)	100Vdc	120pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G2A121J0□□H03□	X8G (Murata)	100Vdc	120pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A151J0□□H03□	X8G (Murata)	100Vdc	150pF±5%	3.6×3.5	2.5	2.5	A2	DB

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RHE5G2A151J0□□H03□	X8G (Murata)	100Vdc	150pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A181J0□□H03□	X8G (Murata)	100Vdc	180pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G2A181J0□□H03□	X8G (Murata)	100Vdc	180pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A221J0□□H03□	X8G (Murata)	100Vdc	220pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G2A221J0□□H03□	X8G (Murata)	100Vdc	220pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A271J0□□H03□	X8G (Murata)	100Vdc	270pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G2A271J0□□H03□	X8G (Murata)	100Vdc	270pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A331J0□□H03□	X8G (Murata)	100Vdc	330pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G2A331J0□□H03□	X8G (Murata)	100Vdc	330pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A391J0□□H03□	X8G (Murata)	100Vdc	390pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G2A391J0□□H03□	X8G (Murata)	100Vdc	390pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A471J0□□H03□	X8G (Murata)	100Vdc	470pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G2A471J0□□H03□	X8G (Murata)	100Vdc	470pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A561J0□□H03□	X8G (Murata)	100Vdc	560pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G2A561J0□□H03□	X8G (Murata)	100Vdc	560pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A681J0□□H03□	X8G (Murata)	100Vdc	680pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G2A681J0□□H03□	X8G (Murata)	100Vdc	680pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A821J0□□H03□	X8G (Murata)	100Vdc	820pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G2A821J0□□H03□	X8G (Murata)	100Vdc	820pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A102J0□□H03□	X8G (Murata)	100Vdc	1000pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G2A102J0□□H03□	X8G (Murata)	100Vdc	1000pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A122J0□□H03□	X8G (Murata)	100Vdc	1200pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G2A122J0□□H03□	X8G (Murata)	100Vdc	1200pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A152J0□□H03□	X8G (Murata)	100Vdc	1500pF±5%	3.6×3.5	2.5	2.5	A2	DB
RHE5G2A152J0□□H03□	X8G (Murata)	100Vdc	1500pF±5%	3.6×3.5	2.5	5.0	K1	M1
RHE5G2A182J1□□H03□	X8G (Murata)	100Vdc	1800pF±5%	4.0×3.5	2.5	2.5	A2	DB
RHE5G2A182J1□□H03□	X8G (Murata)	100Vdc	1800pF±5%	4.0×3.5	2.5	5.0	K1	M1
RHE5G2A222J1□□H03□	X8G (Murata)	100Vdc	2200pF±5%	4.0×3.5	2.5	2.5	A2	DB
RHE5G2A222J1□□H03□	X8G (Murata)	100Vdc	2200pF±5%	4.0×3.5	2.5	5.0	K1	M1
RHE5G2A272J1□□H03□	X8G (Murata)	100Vdc	2700pF±5%	4.0×3.5	2.5	2.5	A2	DB
RHE5G2A272J1□□H03□	X8G (Murata)	100Vdc	2700pF±5%	4.0×3.5	2.5	5.0	K1	M1
RHE5G2A332J1□□H03□	X8G (Murata)	100Vdc	3300pF±5%	4.0×3.5	2.5	2.5	A2	DB
RHE5G2A332J1□□H03□	X8G (Murata)	100Vdc	3300pF±5%	4.0×3.5	2.5	5.0	K1	M1

Two blank columns are filled with the lead style code. Please refer to the 3 columns on the right for the appropriate code.

The last blank column is filled with the packaging code. (B: bulk, A: ammo pack)

High Dielectric Constant Type, X8L Characteristics

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RHEL81H221K0□□H03□	X8L (Murata)	50Vdc	220pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H221K0□□H03□	X8L (Murata)	50Vdc	220pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H331K0□□H03□	X8L (Murata)	50Vdc	330pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H331K0□□H03□	X8L (Murata)	50Vdc	330pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H471K0□□H03□	X8L (Murata)	50Vdc	470pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H471K0□□H03□	X8L (Murata)	50Vdc	470pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H681K0□□H03□	X8L (Murata)	50Vdc	680pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H681K0□□H03□	X8L (Murata)	50Vdc	680pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H102K0□□H03□	X8L (Murata)	50Vdc	1000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H102K0□□H03□	X8L (Murata)	50Vdc	1000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H152K0□□H03□	X8L (Murata)	50Vdc	1500pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H152K0□□H03□	X8L (Murata)	50Vdc	1500pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H222K0□□H03□	X8L (Murata)	50Vdc	2200pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H222K0□□H03□	X8L (Murata)	50Vdc	2200pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H332K0□□H03□	X8L (Murata)	50Vdc	3300pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H332K0□□H03□	X8L (Murata)	50Vdc	3300pF±10%	3.6×3.5	2.5	5.0	K1	M1

Continued from the preceding page.

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RHEL81H472K0□□H03□	X8L (Murata)	50Vdc	4700pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H472K0□□H03□	X8L (Murata)	50Vdc	4700pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H682K0□□H03□	X8L (Murata)	50Vdc	6800pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H682K0□□H03□	X8L (Murata)	50Vdc	6800pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H103K0□□H03□	X8L (Murata)	50Vdc	10000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H103K0□□H03□	X8L (Murata)	50Vdc	10000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H153K0□□H03□	X8L (Murata)	50Vdc	15000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H153K0□□H03□	X8L (Murata)	50Vdc	15000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H223K0□□H03□	X8L (Murata)	50Vdc	22000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H223K0□□H03□	X8L (Murata)	50Vdc	22000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H333K0□□H03□	X8L (Murata)	50Vdc	33000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H333K0□□H03□	X8L (Murata)	50Vdc	33000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H473K0□□H03□	X8L (Murata)	50Vdc	47000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H473K0□□H03□	X8L (Murata)	50Vdc	47000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H683K0□□H03□	X8L (Murata)	50Vdc	68000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H683K0□□H03□	X8L (Murata)	50Vdc	68000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H104K0□□H03□	X8L (Murata)	50Vdc	0.10µF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL81H104K0 - H03	X8L (Murata)	50Vdc	0.10µF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL81H154K1□□H03□	X8L (Murata)	50Vdc	0.15µF±10%	4.0×3.5	2.5	2.5	A2	DB
RHEL81H154K1 - H03	X8L (Murata)	50Vdc	0.15μF±10%	4.0×3.5	2.5	5.0	K1	M1
RHEL81H224K1 □ □ H03 □	X8L (Murata)	50Vdc	0.22µF±10%	4.0×3.5	2.5	2.5	A2	DB
RHEL81H224K1 - H03	X8L (Murata)	50Vdc	0.22µF±10%	4.0×3.5	2.5	5.0	K1	M1
RHEL81H334K1 - H03	X8L (Murata)	50Vdc	0.33μF±10%	4.0×3.5	2.5	2.5	A2	DB
RHEL81H334K1 - H03	X8L (Murata)	50Vdc	0.33μF±10%	4.0×3.5	2.5	5.0	K1	M1
RHEL81H474K2 - H03	X8L (Murata)	50Vdc	0.47μF±10%	5.5×4.0	3.15	2.5	A2	DB
RHEL81H474K2 - H03	X8L (Murata)	50Vdc	0.47μΓ±10% 0.47μF±10%	5.5×4.0	3.15	5.0	K1	M1
RHEL81H684K2 H03	X8L (Murata)	50Vdc	0.47μ1±10% 0.68μF±10%	5.5×4.0	3.15	2.5	A2	DB
RHEL81H684K2 H03	X8L (Murata)	50Vdc	0.68μF±10%	5.5×4.0	3.15	5.0	K1	M1
RHEL81H105K2 H03	X8L (Murata)	50Vdc	1.0μF±10%	5.5×4.0	3.15	2.5	A2	DB
RHEL81H105K2	X8L (Murata)	50Vdc	1.0μF±10% 1.0μF±10%	5.5×4.0	3.15	5.0	K1	M1
RHEL81H155K2	X8L (Murata)	50Vdc	1.5μF±10%	5.5×4.0	3.15	2.5	A2	DB
		50Vdc			3.15	5.0	K1	M1
RHEL81H155K2 H03	X8L (Murata)		1.5µF±10%	5.5×4.0 5.5×4.0	3.15	2.5		DB
RHEL81H225K2 H03	X8L (Murata)	50Vdc	2.2μF±10%				A2	
RHEL81H225K2 H03	X8L (Murata)	50Vdc	2.2μF±10%	5.5×4.0	3.15	5.0	K1	M1
RHEL81H335K3 H03	X8L (Murata)	50Vdc	3.3µF±10%	5.5×5.0	4.0	2.5	A2	DB
RHEL81H335K3 H03	X8L (Murata)	50Vdc	3.3µF±10%	5.5×5.0	4.0	5.0	K1	M1
RHEL81H475K3 H03	X8L (Murata)	50Vdc	4.7µF±10%	5.5×5.0	4.0	2.5	A2	DB
RHEL81H475K3 H03	X8L (Murata)	50Vdc	4.7μF±10%	5.5×5.0	4.0	5.0	K1	M1
RHEL81H106MW H03	X8L (Murata)	50Vdc	10µF±20%	5.5×7.5	4.0	5.0	K1	M1
RHEL82A221K0 H03	X8L (Murata)	100Vdc	220pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL82A221K0 H03	X8L (Murata)	100Vdc	220pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL82A331K0 H03	X8L (Murata)	100Vdc	330pF±10%	3.6×3.5	2.5	2.5	A2	DB M1
RHEL82A331K0 H03	X8L (Murata)	100Vdc	330pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL82A471K0 H03	X8L (Murata)	100Vdc	470pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL82A471K0 H03	X8L (Murata)	100Vdc	470pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL82A681K0 H03	X8L (Murata)	100Vdc	680pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL82A681K0 H03	X8L (Murata)	100Vdc	680pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL82A102K0 H03	X8L (Murata)	100Vdc	1000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL82A102K0 H03	X8L (Murata)	100Vdc	1000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL82A152K0 H03	X8L (Murata)	100Vdc	1500pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL82A152K0 H03	X8L (Murata)	100Vdc	1500pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL82A222K0□□H03□	X8L (Murata)	100Vdc	2200pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL82A222K0□□H03□	X8L (Murata)	100Vdc	2200pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL82A332K0□□H03□	X8L (Murata)	100Vdc	3300pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL82A332K0□□H03□	X8L (Murata)	100Vdc	3300pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL82A472K0□□H03□	X8L (Murata)	100Vdc	4700pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL82A472K0□□H03□	X8L (Murata)	100Vdc	4700pF±10%	3.6×3.5	2.5	5.0	K1	M1



Continued from the preceding page.

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RHEL82A682K0□□H03□	X8L (Murata)	100Vdc	6800pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL82A682K0□□H03□	X8L (Murata)	100Vdc	6800pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL82A103K0□□H03□	X8L (Murata)	100Vdc	10000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL82A103K0□□H03□	X8L (Murata)	100Vdc	10000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL82A153K0□□H03□	X8L (Murata)	100Vdc	15000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL82A153K0□□H03□	X8L (Murata)	100Vdc	15000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL82A223K0□□H03□	X8L (Murata)	100Vdc	22000pF±10%	3.6×3.5	2.5	2.5	A2	DB
RHEL82A223K0□□H03□	X8L (Murata)	100Vdc	22000pF±10%	3.6×3.5	2.5	5.0	K1	M1
RHEL82A333K1□□H03□	X8L (Murata)	100Vdc	33000pF±10%	4.0×3.5	2.5	2.5	A2	DB
RHEL82A333K1□□H03□	X8L (Murata)	100Vdc	33000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RHEL82A473K1□□H03□	X8L (Murata)	100Vdc	47000pF±10%	4.0×3.5	2.5	2.5	A2	DB
RHEL82A473K1□□H03□	X8L (Murata)	100Vdc	47000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RHEL82A683K1□□H03□	X8L (Murata)	100Vdc	68000pF±10%	4.0×3.5	2.5	2.5	A2	DB
RHEL82A683K1□□H03□	X8L (Murata)	100Vdc	68000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RHEL82A104K1□□H03□	X8L (Murata)	100Vdc	0.10µF±10%	4.0×3.5	2.5	2.5	A2	DB
RHEL82A104K1□□H03□	X8L (Murata)	100Vdc	0.10µF±10%	4.0×3.5	2.5	5.0	K1	M1
RHEL82A154K2□□H03□	X8L (Murata)	100Vdc	0.15µF±10%	5.5×4.0	3.15	2.5	A2	DB
RHEL82A154K2□□H03□	X8L (Murata)	100Vdc	0.15µF±10%	5.5×4.0	3.15	5.0	K1	M1
RHEL82A224K2□□H03□	X8L (Murata)	100Vdc	0.22µF±10%	5.5×4.0	3.15	2.5	A2	DB
RHEL82A224K2□□H03□	X8L (Murata)	100Vdc	0.22µF±10%	5.5×4.0	3.15	5.0	K1	M1

Two blank columns are filled with the lead style code. Please refer to the 3 columns on the right for the appropriate code.

The last blank column is filled with the packaging code. (B: bulk, A: ammo pack)

Specifications and Test Methods

			Specifi	cation					
No.	AEC-Q200	Test Item	Temperature Compensating Type (Char. X8G)	High Dielectric Constant Type (Char. X8L)	AEC-Q200 Test Method				
1	Pre-and P	ost-Stress Test		-					
	High Tem Exposure	perature (Storage)	The measured and observed ch specifications in the following tal	•					
		Appearance	No defects or abnormalities						
2		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	Within ±12.5%	Sit the capacitor for 1,000±12h at 150±3°C. Let sit for 24±2h at room temperature, then measure.				
		Q/D.F.	Q≧350	0.04 max.					
		I.R.	More than 1,000M Ω or 50M $\Omega \cdot \mu$	ıF (Whichever is smaller)					
	Temperat Cycling	ture	The measured and observed ch specifications in the following tal	•	Perform the 1,000 cycles according to the four heat treatments listed in the following table. Let sit for 24±2h at *room condition,				
		Appearance	No defects or abnormalities exceedating	ept color change of outer	Step 1 2 3 4				
3		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	Within ±12.5%	Temp. (°C) -55+0/-3 Room Temp. 150+3/-0 Room Temp. Time (min.) 15±3 1 15±3 1				
		Q/D.F.	Q≧350	0.05 max.	•Pretreatment Perform the heat treatment at 150+0/-10°C for 60±5 min and				
		I.R.	1,000M Ω or 50M Ω · μF min. (Wi	nichever is smaller)	then let sit for 24±2h at *room condition. (for Char. X8L)				
	Moisture Resistance	e	The measured and observed ch specifications in the following tal	•	Apply the 24h heat (25 to 65°C) and humidity (80 to 98%) treatment shown below, 10 consecutive times.				
		Appearance	No defects or abnormalities		Let sit for 24±2h at *room condition, then measure.				
		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	Within ±12.5%	Humidity Humidity Humidity Humidity Humidity (°C) 90-98% 80-98% 90-98% 80-98% 90-98% 70 65 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4				
		Q/D.F.	Q≧200	0.05 max.	55 50				
4		l.R.	500M Ω or 25M Ω · μF min. (Whice	chever is smaller)	9 4 4 5 6 7 8 9 1011121314 15 16 17 18 19 20 21 22 23 24 Hours				
	Biased H	umidity	The measured and observed ch specifications in the following tal	•	Apply the rated voltage and DC1.3+0.2/-0V (add 6.8kΩ resistor)				
		Appearance	No defects or abnormalities		at 85±3°C and 80 to 85% humidity for 1,000±12h. Remove and let sit for 24±2h at *room condition, then measure.				
5		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	Within ±12.5%	The charge/discharge current is less than 50mA. •Pretreatment				
		Q/D.F.	Q≥200	0.05 max.	Perform the heat treatment at 150+0/-10°C for 60±5 min and				
		I.R.	500M Ω or 25M Ω · μF min. (Which	chever is smaller)	then let sit for 24±2h at *room condition. (for Char. X8L)				
	Operation	nal Life	The measured and observed ch specifications in the following tal	,	Apply 150% of the rated voltage for 1,000±12h at 150±3°C.				
		Appearance	No defects or abnormalities excoonting	ept color change of outer	Let sit for 24±2h at *room condition, then measure. The charge/discharge current is less than 50mA.				
6		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	Within ±12.5%	•Pretreatment Apply test voltage for 60±5 min at test temperature.				
		Q/D.F.	Q≧350	0.04 max.	Remove and let sit for 24±2h at *room condition. (for Char. X8L)				
		I.R.	1,000M Ω or 50M Ω · μF min. (W	nichever is smaller)	(IOI Oliai. AGE)				
7	External \	/isual	No defects or abnormalities		Visual inspection				
8	Physical I	Dimension	Within the specified dimensions		Using calipers and micrometers.				
9	Marking		To be easily legible.		Visual inspection				

 $^{^{\}star}$ "room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmosphere pressure: 86 to 106kPa





Specifications and Test Methods

Continued from the preceding page.

			Specif	ication					
lo.	AEC-Q200	Test Item	Temperature Compensating Type (Char. X8G)	High Dielectric Constant Type (Char. X8L)		AEC-Q200 Test N	Method		
		Appearance	No defects or abnormalities		Per MIL-STD-20				
		Capacitance	Within the specified tolerance			rt (by volume) of ison			
0	Resistance	Q/D.F.	Q≥1,000	0.025 max.	3 parts (by volume) of mineral spirits Solvent 2: Terpene defluxer Solvent 3: 42 parts (by volume) of water 1 part (by volume) of propylene glycol monomethyl ether 1 part (by volume) of monoethanolamine				
U	to Solvents	I.R.	More than 10,000M Ω or 500M Ω	· μF (Whichever is smaller)					
		Appearance	No defects or abnormalities			each direction should			
1	Mechanical	Capacitance	Within the specified tolerance			dicular axes of the te at pulse should be Ha	st specimen (18 shocks).		
•	Shock	Q/D.F.	Q≥1,000	0.025 max.	have a duration: 0.5ms, peak value: 1,500G and velocity change: 4.7m/s.				
		Appearance	No defects or abnormalities		The capacitor sh	ould be subjected to	a simple harmonic motio		
		Capacitance	Within the specified tolerance				e frequency being varied		
2	Vibration	Q/D.F.	Q≥1,000	0.025 max.	uniformly between the approximate limits of 10 and 2,0 The frequency range, from 10 to 2,000Hz and return to should be traversed in approximately 20min. This moti should be applied for 12 items in each 3 mutually perp directions (total of 36 times).				
	Resistance Soldering I		The measured and observed ch specifications in the following ta		The lead wire is immersed in the melted solder 1.5 to 2mm				
		Appearance	No defects or abnormalities				0±1s. The specified items		
3		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	Within ±7.5%	are measured after 24±2h. •Pretreatment				
		Dielectric Strength (Between Terminals)	ngth veen No defects		Perform the heat treatment at 150+0/-10°C for 60±5 min and then let sit for 24±2h at *room condition. (for Char. X8L)				
	Thermal S	Shock	The measured and observed ch specifications in the following ta	Perform the 300 cycles according to the two heat treatments listed in the following table (Maximum transfer time is 20s.).					
		Appearance	No defects or abnormalities		Let sit for 24±2h	at *room condition, t	hen measure.		
4		Capacitance	Within ±5% or ±0.5pF	Within ±12.5%	Step Temp. (°C)	1 -55+0/-3	2 150+3/-0		
7		Change	(Whichever is larger)	VVIIIII ±12.070	Time (min.)	15±3	15±3		
		Q/D.F.	Q≧350	0.05 max.	•Pretreatment				
		I.R.	1,000M Ω or 50M Ω · μF min. (W	hichever is smaller)		at treatment at 150+0 4±2h at *room condi	0/-10°C for 60±5min and tion. (for Char. X8L)		
		Appearance	No defects or abnormalities						
5	ESD	Capacitance	Within the specified tolerance		Dor AEC 0000 0	004			
J	LOD	Q/D.F.	Q≧1,000	0.025 max.	Per AEC-Q200-0	104			
		I.R.	More than 10,000M Ω or 500M Ω	· μF (Whichever is smaller)					
6	Solderabi	lity	Lead wire should be soldered w direction over 95% of the circum		The terminal of a capacitor is dipped into a solution of ethano (JIS-K-8101) and rosin (JIS-K-5902) (25%rosin in weight propotion) and then into molten solder (JIS-Z-3282) for 2±0.5 sec. In both cases the depth of dipping is up to about 1.5 to 2mm from the terminal body. Temp. of solder: 245±5°C Lead Free Solder (Sn-3.0Ag-0.5Cu) 235±5°C H60A or H63A Eutectic Solder				

^{* &}quot;room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmosphere pressure: 86 to 106kPa





Specifications and Test Methods

 $\begin{tabular}{|c|c|c|c|}\hline \searrow \\\hline \end{tabular}$ Continued from the preceding page.

				Specif	ication			
о.	AEC-Q200	Test Item	Temperature Compensating Type (Char. X8G)		High Dielectric Constant Type (Char. X8L)	AEC-Q200 To	est Method	
		Appearance	No defects or a	bnormalities		Visual inspection.		
		Capacitance	Within the spec	cified tolerance		The capacitance, Q/D.F. should I frequency and voltage shown in		
		Q/D.F.	Q≥1,000		0.025 max.	Char. Nominal Cap. Frequency X8G C≤1,000pF 1±0. X8G C>1000pF 1±0.	uency Voltage 1MHz AC0.5 to 5V (r.m.s.) .1kHz AC1±0.2V (r.m.s.) .1kHz AC1±0.2V (r.m.s.)	
		Insulation Resistance	Room Temperature	10,000MΩ or 5 (Whichever is s	00MΩ · μF min. :maller)	The insulation resistance should be measured at 25±3°C with DC voltage not exceeding the rated voltage at normal temperature and humidity and within 2min. of charging. (Charge/Discharge current ≤ 50mA.)		
7	Electrical Charac-	(I.R.)	High Temperature	100M Ω or 5M Ω (Whichever is s		The insulation resistance should be measured at 150±3°C wit a DC voltage not exceeding the rated voltage at normal temperature and humidity and within 2min. of charging. (Charge/Discharge current ≤ 50mA.)		
	terization		Between Terminals	No defects or a	bnormalities	The capacitor should not be damaged when DC voltage of 300% of the rated voltage (for Char. X8G) or DC voltage of 250% of the rated voltage (for Char. X8L) is applied between the terminations for 1 to 5 seconds. (Charge/Discharge current ≤ 50mA.)		
		Dielectric Strength	Body Insulation	No defects or a	bnormalities	The capacitor is placed in a contained with metal balls of 1mm diameter that each terminal, short-circuit is approximately 2mm from the ball and 250% of the rated DC voltag impressed for 1 to 5 seconds between capacitor terminals and metal balls. (Charge/Discharge current ≤ 50r	r so s kept ls, le is Approx. 2n	
3	Terminal Strength	Tensile Strength	Termination no	t to be broken or	loosened	As in the figure, fix the capacitor apply the force gradually to each in the radial direction of the capa until reaching 10N and then keep force applied for 10±1 seconds.	lead	
	Strength	Bending Strength	Termination no	t to be broken or	loosened	Each lead wire should be subjected		
						The capacitance change should each specified temperature step.		
						Step	Temperature (°C)	
			Within the spec	rified		1 2	25±2 -55±3	
			Tolerance.			3	25±2	
	Capacitar	nce	(Table A)		Within ±15%	4	150±3	
)	Temperat	ure	•		(Temp. Range: -55 to +125°C) Within +15/-40%	5	25±2	
	Character	ristics	Capacitance Drift is within ±0.2% or ±0.05pF (Whichever is larger)		(Temp. Range: +125 to +150°C)	The temperature coefficient or the change is determined using the castep 3 as a reference. •Pretreatment Perform the heat treatment at 1 then let sit for 24±2h at *room castep 1.	capacitance measured in 50+0/-10°C for 60±5 min and condition.	

 $^{^{\}star}$ "room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmosphere pressure: 86 to 106kPa

Table A

		Nominal Values									
(Naminal Values	Capacitance Change from 25°C (%)								
	Char.		-55	5°C	-30	0°C	-10°C				
			Max.	Min.	Max.	Min.	Max.	Min.			
	YAG	0+30	0.58	_0 24	0.40	_0.17	0.25	_0 11			

^{*} Nominal values denote the temperature coefficient within a range of 25°C to 150°C.



Radial Lead Type Monolithic Ceramic Capacitors



RDE Series (For General Use Only) (DC25V-DC1kV)

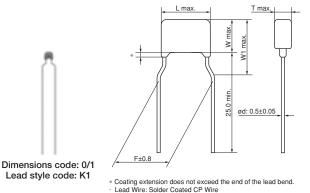
■ Features

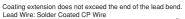
- 1. Small size and large capacitance
- 2. Low ESR characteristics for high frequency
- 3. Meet LF (Lead Free) and HF (Halogen Free)
- 4. Flow soldering is available, but re-flow soldering is not available.

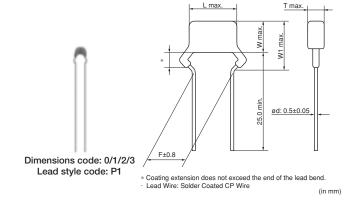
Applications

General electronic equipment

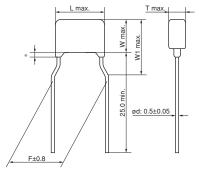
(Do not use for automotive-related power train and safety equipment.)







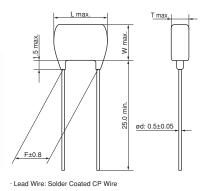




Coating extension does not exceed the end of the lead bend Lead Wire: Solder Coated CP Wire



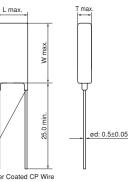
Dimensions code: 5 Lead style code: B1



(in mm)

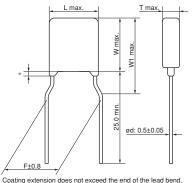






(in mm)

Dimensions code: W Lead style code: K1



Lead Wire: Solder Coated CP Wire

Dimensions

Dimensions and	Dimensions (mm)								
Lead Style Code	L	W	W1	Т	F	d			
0P1/0S1	5.0	3.5	6.0		2.5	0.5			
0K1/0M1	4.0	3.5	6.0		5.0	0.5			
1P1/1S1	5.0	3.5	5.0		2.5	0.5			
1K1/1M1	4.5	3.5	5.0		5.0	0.5			
2P1/2S1	5.5	4.0	6.0		2.5	0.5			
2K1/2M1	5.5	4.0	6.0	See the individual	5.0	0.5			
3P1/3S1	5.5	5.0	7.5	product specification	2.5	0.5			
3K1/3M1	5.5	5.0	7.5		5.0	0.5			
4K1/4M1	7.5	5.5	8.0		5.0	0.5			
5B1/5E1	7.5	7.5*	-		5.0	0.5			
UB1/UE1	7.7	12.5*	-		5.0	0.5			
WK1/WM1	5.5	7.5	10.0		5.0	0.5			

*DC630V, DC1kV: W+0.5mm



■ Marking

■ Marking														
Rate	ted tage	DC	25V			DC50V				DC100V		DC250V	DC630V	DC1kV
Dimensions Characteristics Cha		X7S	X7R	COG	X7S	X7R	F	Y5V	COG	X7S	X7R		X7R, U2J	
0		224K	104K	A	-	224K	<u>473</u>	103Z	A	_	224K	_	_	_
1			-	\/	-		-	-	102J	_		U 102J	_	-
2		(M475) K2C	-	-	(M 475 K5C)	(M 105 K5C)	-	-	_	_	(M 105 K1C)	(U2J) (U2J) (X7R)	(U2J) (U2J) (U2J) (X7R)	102 JAU (U2J) (MKAC) (X7R)
3, 4, W		(M226 K2C	-	-	-	(M335 K5C)	-	-	-	(M225 K1C	-	(W473 J4U (U2J) (W224 K4C (X7R)	(M103 J7U (U2J) (M104 K7C (X7R)	(M472 JAU (U2J) (M333 KAC (X7R)
5, U		-	ı	-	-	ı	-	-	-	-	-	- (M) 474 K4C (X7R)	(U2J) (U2J) (W474 M7C (X7R)	(U2J) (U2J) (M 104 KAC (X7R)
Temperature Characteristics			vith code omitted (F					V char.: F	, U2J cha	r.: U)				
Nominal Capacitano	се	Under 10	00pF: Actu	ıal value	100pF a	nd over: N	larked wit	h 3 figures	3					
Capacitance Tolerar	nce		Marked with code A part is omitted (Please refer to the marking example.)											
Rated Voltage		Lower ho	with code orizontal linomitted (F	ne for F cl	nar.			250V: 4, D	C630V: 7	, DC1kV:	A)			
Manufacturer's Identification		Marked v A part is	vith M omitted (F	Please refe	er to the n	narking ex	ample.)							

Temperature Compensating Type, C0G/U2J Characteristics

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RDE5C1H1R0C0□□H03□	C0G (EIA)	50Vdc	1.0pF±0.25pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H1R0C0□□H03□	C0G (EIA)	50Vdc	1.0pF±0.25pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H2R0C0□□H03□	C0G (EIA)	50Vdc	2.0pF±0.25pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H2R0C0□□H03□	C0G (EIA)	50Vdc	2.0pF±0.25pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H3R0C0□□H03□	C0G (EIA)	50Vdc	3.0pF±0.25pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H3R0C0□□H03□	C0G (EIA)	50Vdc	3.0pF±0.25pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H4R0C0□□H03□	C0G (EIA)	50Vdc	4.0pF±0.25pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H4R0C0□□H03□	C0G (EIA)	50Vdc	4.0pF±0.25pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H5R0C0□□H03□	C0G (EIA)	50Vdc	5.0pF±0.25pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H5R0C0□□H03□	C0G (EIA)	50Vdc	5.0pF±0.25pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H6R0D0□□H03□	C0G (EIA)	50Vdc	6.0pF±0.5pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H6R0D0□□H03□	C0G (EIA)	50Vdc	6.0pF±0.5pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H7R0D0□□H03□	C0G (EIA)	50Vdc	7.0pF±0.5pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H7R0D0□□H03□	C0G (EIA)	50Vdc	7.0pF±0.5pF	5.0×3.5	2.5	2.5	P1	S1





Continued from the preceding page.

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RDE5C1H8R0D0□□H03□	C0G (EIA)	50Vdc	8.0pF±0.5pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H8R0D0□□H03□	C0G (EIA)	50Vdc	8.0pF±0.5pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H9R0D0□□H03□	C0G (EIA)	50Vdc	9.0pF±0.5pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H9R0D0□□H03□	C0G (EIA)	50Vdc	9.0pF±0.5pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H100J0□□H03□	C0G (EIA)	50Vdc	10pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H100J0□□H03□	C0G (EIA)	50Vdc	10pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H120J0□□H03□	C0G (EIA)	50Vdc	12pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H120J0□□H03□	C0G (EIA)	50Vdc	12pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H150J0□□H03□	C0G (EIA)	50Vdc	15pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H150J0□□H03□	C0G (EIA)	50Vdc	15pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H180J0□□H03□	C0G (EIA)	50Vdc	18pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H180J0□□H03□	C0G (EIA)	50Vdc	18pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H220J0□□H03□	C0G (EIA)	50Vdc	22pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H220J0□□H03□	C0G (EIA)	50Vdc	22pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H270J0 H03	COG (EIA)	50Vdc	27pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H270J0 H03	COG (EIA)	50Vdc	27pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H330J0 H03	COG (EIA)	50Vdc	33pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H330J0 H03	COG (EIA)	50Vdc	33pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H390J0 H03	COG (EIA)	50Vdc	39pF±5%	4.0×3.5	2.5	5.0	K1 P1	M1
RDE5C1H390J0 H03	COG (EIA)	50Vdc	39pF±5%	5.0×3.5	2.5	2.5		S1 M1
RDE5C1H470J0□□H03□ RDE5C1H470J0□□H03□	COG (EIA)	50Vdc 50Vdc	47pF±5%	4.0×3.5 5.0×3.5	2.5	5.0 2.5	K1 P1	M1 S1
RDE5C1H560J0 H03	COG (EIA)	50Vdc	47pF±5% 56pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H560J0 H03	COG (EIA)	50Vdc	56pF±5%	4.0x3.5 5.0×3.5	2.5	2.5	P1	S1
RDE5C1H680J0 H03	COG (EIA)	50Vdc	68pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H680J0 H03	COG (EIA)	50Vdc	68pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H820J0 H03	COG (EIA)	50Vdc	82pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H820J0	COG (EIA)	50Vdc	82pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H101J0 H03	COG (EIA)	50Vdc	100pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H101J0 H03	COG (EIA)	50Vdc	100pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H121J0□□H03□	C0G (EIA)	50Vdc	120pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H121J0□□H03□	C0G (EIA)	50Vdc	120pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H151J0 H03	C0G (EIA)	50Vdc	150pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H151J0□□H03□	C0G (EIA)	50Vdc	150pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H181J0□□H03□	C0G (EIA)	50Vdc	180pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H181J0□□H03□	C0G (EIA)	50Vdc	180pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H221J0□□H03□	C0G (EIA)	50Vdc	220pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H221J0□□H03□	C0G (EIA)	50Vdc	220pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H271J0□□H03□	C0G (EIA)	50Vdc	270pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H271J0□□H03□	C0G (EIA)	50Vdc	270pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H331J0□□H03□	C0G (EIA)	50Vdc	330pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H331J0□□H03□	C0G (EIA)	50Vdc	330pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H391J0 H03	COG (EIA)	50Vdc	390pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H391J0 H03	COG (EIA)	50Vdc	390pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H471J0 H03	COG (EIA)	50Vdc	470pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H471J0 H03	COG (EIA)	50Vdc	470pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H561J0 H03	COG (EIA)	50Vdc	560pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H561J0 H03	COG (EIA)	50Vdc	560pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H681J0□□H03□	COG (EIA)	50Vdc	680pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H681J0□□H03□	COG (EIA)	50Vdc	680pF±5%	5.0×3.5	2.5	2.5	P1	S1 M1
RDE5C1H821J0□□H03□	COG (EIA)	50Vdc	820pF±5%	4.0×3.5	2.5	5.0 2.5	K1 P1	M1 S1
RDE5C1H821J0□□H03□ RDE5C1H102J0□□H03□	C0G (EIA)	50Vdc 50Vdc	820pF±5% 1000pF±5%	5.0×3.5 4.0×3.5	2.5	5.0	K1	M1
RDE5C1H102J0 H03	COG (EIA)	50Vdc 50Vdc	1000pF±5%	4.0×3.5 5.0×3.5	2.5	2.5	P1	S1
RDE5C1H122J0 H03	COG (EIA)	50Vdc	1200pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H122J0 H03	COG (EIA)	50Vdc	1200pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H152J0 H03	COG (EIA)	50Vdc	1500pF±5%	4.0×3.5	2.5	5.0	K1	M1
		50 4 40	1000pi ±076	1.0.0.0	2.0	0.0	13.1	1411

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RDE5C1H152J0 H03	C0G (EIA)	50Vdc	1500pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H182J0□□H03□	C0G (EIA)	50Vdc	1800pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H182J0□□H03□	C0G (EIA)	50Vdc	1800pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H222J0□□H03□	C0G (EIA)	50Vdc	2200pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H222J0□□H03□	C0G (EIA)	50Vdc	2200pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H272J0□□H03□	C0G (EIA)	50Vdc	2700pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H272J0□□H03□	C0G (EIA)	50Vdc	2700pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H332J0□□H03□	COG (EIA)	50Vdc	3300pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H332J0□□H03□	C0G (EIA)	50Vdc	3300pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H392J0□□H03□	COG (EIA)	50Vdc	3900pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C1H392J0□□H03□	C0G (EIA)	50Vdc	3900pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C1H472J1□□H03□	C0G (EIA)	50Vdc	4700pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE5C1H472J1□□H03□	C0G (EIA)	50Vdc	4700pF±5%	5.0×3.5	3.15	2.5	P1	S1
RDE5C1H562J1□□H03□	C0G (EIA)	50Vdc	5600pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE5C1H562J1□□H03□	C0G (EIA)	50Vdc	5600pF±5%	5.0×3.5	3.15	2.5	P1	S1
RDE5C1H682J1□□H03□	C0G (EIA)	50Vdc	6800pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE5C1H682J1□□H03□	C0G (EIA)	50Vdc	6800pF±5%	5.0×3.5	3.15	2.5	P1	S1
RDE5C1H822J1□□H03□	C0G (EIA)	50Vdc	8200pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE5C1H822J1□□H03□	C0G (EIA)	50Vdc	8200pF±5%	5.0×3.5	3.15	2.5	P1	S1
RDE5C1H103J1□□H03□	C0G (EIA)	50Vdc	10000pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE5C1H103J1□□H03□	C0G (EIA)	50Vdc	10000pF±5%	5.0×3.5	3.15	2.5	P1	S1
RDE5C1H123J1□□H03□	C0G (EIA)	50Vdc	12000pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE5C1H123J1□□H03□	COG (EIA)	50Vdc	12000pF±5%	5.0×3.5	3.15	2.5	P1	S1
RDE5C1H153J1 H03	C0G (EIA)	50Vdc	15000pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE5C1H153J1 H03	C0G (EIA)	50Vdc	15000pF±5%	5.0×3.5	3.15	2.5	P1	S1
RDE5C1H183J1 H03	COG (EIA)	50Vdc	18000pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE5C1H183J1 H03	COG (EIA)	50Vdc	18000pF±5%	5.0×3.5	3.15	2.5	P1	S1
RDE5C1H223J1 H03	COG (EIA)	50Vdc	22000pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE5C1H223J1□□H03□	COG (EIA)	50Vdc	22000pF±5%	5.0×3.5	3.15	2.5	P1	S1
RDE5C2A1R0C0□□H03□	COG (EIA)	100Vdc	1.0pF±0.25pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A1R0C0□□H03□	COG (EIA)	100Vdc	1.0pF±0.25pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A2R0C0□□H03□	C0G (EIA)	100Vdc	2.0pF±0.25pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A2R0C0□□H03□	C0G (EIA)	100Vdc	2.0pF±0.25pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A3R0C0 H03	C0G (EIA)	100Vdc	3.0pF±0.25pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A3R0C0 H03	C0G (EIA)	100Vdc	3.0pF±0.25pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A4R0C0□□H03□	C0G (EIA)	100Vdc	4.0pF±0.25pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A4R0C0□□H03□	C0G (EIA)	100Vdc	4.0pF±0.25pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A5R0C0□□H03□	COG (EIA)	100Vdc	5.0pF±0.25pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A5R0C0□□H03□	COG (EIA)	100Vdc	5.0pF±0.25pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A6R0D0□□H03□	COG (EIA)	100Vdc	6.0pF±0.5pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A6R0D0□□H03□	COG (EIA)	100Vdc	6.0pF±0.5pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A7R0D0□□H03□	COG (EIA)	100Vdc	7.0pF±0.5pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A7R0D0 H03	COG (EIA)	100Vdc	7.0pF±0.5pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A8R0D0□□H03□	COG (EIA)	100Vdc	8.0pF±0.5pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A8R0D0 H03	COG (EIA)	100Vdc	8.0pF±0.5pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A9R0D0□□H03□	COG (EIA)	100Vdc	9.0pF±0.5pF	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A9R0D0 H03	COG (EIA)	100Vdc	9.0pF±0.5pF	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A100J0□□H03□	COG (EIA)	100Vdc	10pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A100J0 H03	COG (EIA)	100Vdc	10pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A120J0 H03	COG (EIA)	100Vdc	12pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A120J0 H03	COG (EIA)	100Vdc	12pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A150J0	COG (EIA)	100Vdc	15pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A150J0 H03	COG (EIA)	100Vdc	15pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A180J0 H03	COG (EIA)	100Vdc	18pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A180J0 H03	COG (EIA)	100Vdc	18pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A220J0 H03	COG (EIA)	100Vdc	22pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A220J0 H03	COG (EIA)	100Vdc	22pF±5%	5.0×3.5	2.5	2.5	P1	S1
	000 (LIA)	100 400		0.0.0.0	2.0	2.5	1 1	

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RDE5C2A270J0□□H03□	C0G (EIA)	100Vdc	27pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A270J0□□H03□	C0G (EIA)	100Vdc	27pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A330J0□□H03□	C0G (EIA)	100Vdc	33pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A330J0□□H03□	C0G (EIA)	100Vdc	33pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A390J0□□H03□	C0G (EIA)	100Vdc	39pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A390J0□□H03□	C0G (EIA)	100Vdc	39pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A470J0□□H03□	C0G (EIA)	100Vdc	47pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A470J0□□H03□	C0G (EIA)	100Vdc	47pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A560J0□□H03□	C0G (EIA)	100Vdc	56pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A560J0□□H03□	C0G (EIA)	100Vdc	56pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A680J0□□H03□	C0G (EIA)	100Vdc	68pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A680J0□□H03□	C0G (EIA)	100Vdc	68pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A820J0□□H03□	C0G (EIA)	100Vdc	82pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A820J0□□H03□	C0G (EIA)	100Vdc	82pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A101J0□□H03□	C0G (EIA)	100Vdc	100pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A101J0□□H03□	C0G (EIA)	100Vdc	100pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A121J0□□H03□	C0G (EIA)	100Vdc	120pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A121J0□□H03□	C0G (EIA)	100Vdc	120pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A151J0 H03	C0G (EIA)	100Vdc	150pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A151J0 H03	COG (EIA)	100Vdc	150pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A181J0 H03	COG (EIA)	100Vdc	180pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A181J0 H03	COG (EIA)	100Vdc	180pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A221J0 H03	COG (EIA)	100Vdc	220pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A221J0 H03	COG (EIA)	100Vdc	220pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A271J0 H03	COG (EIA)	100Vdc	270pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A271J0 H03	COG (EIA)	100Vdc	270pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A331J0 H03	COG (EIA)	100Vdc	330pF±5%	4.0×3.5	2.5	5.0	K1 P1	M1
RDE5C2A331J0 H03	COG (EIA)	100Vdc 100Vdc	330pF±5%	5.0×3.5	2.5	2.5 5.0	K1	S1 M1
RDE5C2A391J0 H03 RDE5C2A391J0 H03	C0G (EIA)	100Vdc	390pF±5% 390pF±5%	4.0×3.5 5.0×3.5	2.5	2.5	P1	S1
RDE5C2A471J0 H03	COG (EIA)	100Vdc	470pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A471J0 H03	COG (EIA)	100Vdc	470pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A561J0 H03	COG (EIA)	100Vdc	560pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A561J0 H03	COG (EIA)	100Vdc	560pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A681J0 H03	COG (EIA)	100Vdc	680pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A681J0 H03	COG (EIA)	100Vdc	680pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A821J0 H03	C0G (EIA)	100Vdc	820pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A821J0□□H03□	COG (EIA)	100Vdc	820pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A102J0□□H03□	COG (EIA)	100Vdc	1000pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A102J0□□H03□	COG (EIA)	100Vdc	1000pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A122J0□□H03□	C0G (EIA)	100Vdc	1200pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A122J0□□H03□	C0G (EIA)	100Vdc	1200pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A152J0□□H03□	C0G (EIA)	100Vdc	1500pF±5%	4.0×3.5	2.5	5.0	K1	M1
RDE5C2A152J0□□H03□	C0G (EIA)	100Vdc	1500pF±5%	5.0×3.5	2.5	2.5	P1	S1
RDE5C2A182J1□□H03□	C0G (EIA)	100Vdc	1800pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE5C2A182J1□□H03□	C0G (EIA)	100Vdc	1800pF±5%	5.0×3.5	3.15	2.5	P1	S1
RDE5C2A222J1□□H03□	C0G (EIA)	100Vdc	2200pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE5C2A222J1□□H03□	C0G (EIA)	100Vdc	2200pF±5%	5.0×3.5	3.15	2.5	P1	S1
RDE5C2A272J1□□H03□	C0G (EIA)	100Vdc	2700pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE5C2A272J1□□H03□	C0G (EIA)	100Vdc	2700pF±5%	5.0×3.5	3.15	2.5	P1	S1
RDE5C2A332J1□□H03□	C0G (EIA)	100Vdc	3300pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE5C2A332J1□□H03□	C0G (EIA)	100Vdc	3300pF±5%	5.0×3.5	3.15	2.5	P1	S1
RDE7U2E101J1□□H03□	U2J (EIA)	250Vdc	100pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE7U2E151J1□□H03□	U2J (EIA)	250Vdc	150pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE7U2E221J1□□H03□	U2J (EIA)	250Vdc	220pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE7U2E331J1□□H03□	U2J (EIA)	250Vdc	330pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE7U2E471J1□□H03□	U2J (EIA)	250Vdc	470pF±5%	4.5×3.5	3.15	5.0	K1	M1

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RDE7U2E681J1□□H03□	U2J (EIA)	250Vdc	680pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE7U2E102J1□□H03□	U2J (EIA)	250Vdc	1000pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE7U2E152J1□□H03□	U2J (EIA)	250Vdc	1500pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE7U2E222J1□□H03□	U2J (EIA)	250Vdc	2200pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE7U2E332J1□□H03□	U2J (EIA)	250Vdc	3300pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE7U2E472J1□□H03□	U2J (EIA)	250Vdc	4700pF±5%	4.5×3.5	3.15	5.0	K1	M1
RDE7U2E682J2□□H03□	U2J (EIA)	250Vdc	6800pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2E103J2□□H03□	U2J (EIA)	250Vdc	10000pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2E153J2□□H03□	U2J (EIA)	250Vdc	15000pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2E223J2□□H03□	U2J (EIA)	250Vdc	22000pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2E333J3□□H03□	U2J (EIA)	250Vdc	33000pF±5%	5.5×5.0	4.0	5.0	K1	M1
RDE7U2E473J3□□H03□	U2J (EIA)	250Vdc	47000pF±5%	5.5×5.0	4.0	5.0	K1	M1
RDE7U2J100J2□□H03□	U2J (EIA)	630Vdc	10pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2J150J2□□H03□	U2J (EIA)	630Vdc	15pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2J220J2 H03	U2J (EIA)	630Vdc	22pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2J330J2 H03	U2J (EIA)	630Vdc	33pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2J470J2 H03	U2J (EIA)	630Vdc	47pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2J680J2□□H03□	U2J (EIA)	630Vdc	68pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2J101J2 H03	U2J (EIA)	630Vdc	100pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2J151J2 H03	U2J (EIA)	630Vdc	150pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2J131J2 H03 H03	U2J (EIA)	630Vdc	220pF±5%	5.5×4.0 5.5×4.0	3.15	5.0	K1	M1
	<u> </u>	630Vdc			3.15	5.0	K1	M1
RDE7U2J331J2 H03	U2J (EIA)		330pF±5%	5.5×4.0			K1	
RDE7U2J471J2 H03	U2J (EIA)	630Vdc	470pF±5%	5.5×4.0	3.15	5.0		M1
RDE7U2J681J2 H03	U2J (EIA)	630Vdc	680pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2J102J2 H03	U2J (EIA)	630Vdc	1000pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2J152J2 H03	U2J (EIA)	630Vdc	1500pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2J222J2 H03	U2J (EIA)	630Vdc	2200pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2J332J2 H03	U2J (EIA)	630Vdc	3300pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2J472J2 H03	U2J (EIA)	630Vdc	4700pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U2J682J3 H03	U2J (EIA)	630Vdc	6800pF±5%	5.5×5.0	4.0	5.0	K1	M1
RDE7U2J103J3 H03	U2J (EIA)	630Vdc	10000pF±5%	5.5×5.0	4.0	5.0	K1	M1
RDE7U2J153J4 H03	U2J (EIA)	630Vdc	15000pF±5%	7.5×5.5	4.0	5.0	K1	M1
RDE7U2J223J4 H03	U2J (EIA)	630Vdc	22000pF±5%	7.5×5.5	4.0	5.0	K1	M1
RDE7U2J333J5 H03	U2J (EIA)	630Vdc	33000pF±5%	7.5×8.0	4.0	5.0	B1	E1
RDE7U2J473J5 H03	U2J (EIA)	630Vdc	47000pF±5%	7.5×8.0	4.0	5.0	B1	E1
RDE7U2J943JU H03	U2J (EIA)	630Vdc	94000pF±5%	7.7×13.0	4.0	5.0	B1	E1
RDE7U3A100J2 H03	U2J (EIA)	1000Vdc	10pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U3A150J2 H03	U2J (EIA)	1000Vdc	15pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U3A220J2 H03	U2J (EIA)	1000Vdc	22pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U3A330J2 H03	U2J (EIA)	1000Vdc	33pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U3A470J2 H03	U2J (EIA)	1000Vdc	47pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U3A680J2 H03	U2J (EIA)	1000Vdc	68pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U3A101J2 H03	U2J (EIA)	1000Vdc	100pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U3A151J2 H03	U2J (EIA)	1000Vdc	150pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U3A221J2 H03	U2J (EIA)	1000Vdc	220pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U3A331J2 H03	U2J (EIA)	1000Vdc	330pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U3A471J2 H03	U2J (EIA)	1000Vdc	470pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U3A681J2□□H03□	U2J (EIA)	1000Vdc	680pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U3A102J2□□H03□	U2J (EIA)	1000Vdc	1000pF±5%	5.5×4.0	3.15	5.0	K1	M1
RDE7U3A152J3□□H03□	U2J (EIA)	1000Vdc	1500pF±5%	5.5×5.0	4.0	5.0	K1	M1
RDE7U3A222J3□□H03□	U2J (EIA)	1000Vdc	2200pF±5%	5.5×5.0	4.0	5.0	K1	M1
RDE7U3A332J4□□H03□	U2J (EIA)	1000Vdc	3300pF±5%	7.5×5.5	4.0	5.0	K1	M1
RDE7U3A472J4□□H03□	U2J (EIA)	1000Vdc	4700pF±5%	7.5×5.5	4.0	5.0	K1	M1
RDE7U3A682J5□□H03□	U2J (EIA)	1000Vdc	6800pF±5%	7.5×8.0	4.0	5.0	B1	E1
RDE7U3A103J5□□H03□	U2J (EIA)	1000Vdc	10000pF±5%	7.5×8.0	4.0	5.0	B1	E1
RDE7U3A203JU□□H03□	U2J (EIA)	1000Vdc	20000pF±5%	7.7×13.0	4.0	5.0	B1	E1

Two blank columns are filled with the lead style code. Please refer to the 3 columns on the right for the appropriate code.

The last blank column is filled with the packaging code. (B: bulk, A: ammo pack)



High Dielectric Constant Type, X7R/X7S Characteristics

Part Number	Temp.	Rated	Capacitance	Dimensions LxW	Dimension	Lead Space	Lead Style Code	Lead Style Code
	Char.	Voltage	0.1	(mm)	(mm)	(mm)	Bulk	Taping
RDER71E104K0 H03	X7R (EIA)	25Vdc	0.1µF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71E104K0 H03	X7R (EIA)	25Vdc	0.1μF±10%	5.0×3.5	2.5	2.5	P1	S1
RDEC71E224K0 H03	X7S (EIA)	25Vdc	0.22µF±10%	4.0×3.5	2.5	5.0	K1	M1
RDEC71E224K0 H03	X7S (EIA)	25Vdc	0.22µF±10%	5.0×3.5	2.5	2.5	P1	S1
RDEC71E474K0 H03	X7S (EIA)	25Vdc	0.47µF±10%	4.0×3.5	2.5	5.0	K1	M1
RDEC71E474K0 H03	X7S (EIA)	25Vdc	0.47µF±10%	5.0×3.5	2.5	2.5	P1	S1
RDEC71E105K0 H03	X7S (EIA)	25Vdc	1.0µF±10%	4.0×3.5	2.5	5.0	K1	M1
RDEC71E105K0□□H03□	X7S (EIA)	25Vdc	1.0µF±10%	5.0×3.5	2.5	2.5	P1	S1
RDEC71E225K1 H03	X7S (EIA)	25Vdc	2.2µF±10%	4.5×3.5	3.15	5.0	K1	M1
RDEC71E225K1□□H03□	X7S (EIA)	25Vdc	2.2µF±10%	5.0×3.5	3.15	2.5	P1	S1
RDEC71E475K2 H03	X7S (EIA)	25Vdc	4.7μF±10%	5.5×4.0	3.15	2.5	P1	S1
RDEC71E475K2□□H03□	X7S (EIA)	25Vdc	4.7μF±10%	5.5×4.0	3.15	5.0	K1	M1
RDEC71E106K2□□H03□	X7S (EIA)	25Vdc	10μF±10%	5.5×4.0	3.15	2.5	P1	S1
RDEC71E106K2□□H03□	X7S (EIA)	25Vdc	10μF±10%	5.5×4.0	3.15	5.0	K1	M1
RDEC71E226K3 H03	X7S (EIA)	25Vdc	22µF±10%	5.5×5.0	4.0	2.5	P1	S1
RDEC71E226K3 H03	X7S (EIA)	25Vdc	22µF±10%	5.5×5.0	4.0	5.0	K1	M1
RDEC71E476MW H03	X7S (EIA)	25Vdc	47μF±20%	5.5×7.5	4.0	5.0	K1	M1
RDER71H221K0□□H03□	X7R (EIA)	50Vdc	220pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H221K0□□H03□	X7R (EIA)	50Vdc	220pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H331K0□□H03□	X7R (EIA)	50Vdc	330pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H331K0□□H03□	X7R (EIA)	50Vdc	330pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H471K0□□H03□	X7R (EIA)	50Vdc	470pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H471K0□□H03□	X7R (EIA)	50Vdc	470pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H681K0□□H03□	X7R (EIA)	50Vdc	680pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H681K0□□H03□	X7R (EIA)	50Vdc	680pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H102K0□□H03□	X7R (EIA)	50Vdc	1000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H102K0□□H03□	X7R (EIA)	50Vdc	1000pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H152K0□□H03□	X7R (EIA)	50Vdc	1500pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H152K0□□H03□	X7R (EIA)	50Vdc	1500pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H222K0□□H03□	X7R (EIA)	50Vdc	2200pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H222K0□□H03□	X7R (EIA)	50Vdc	2200pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H332K0□□H03□	X7R (EIA)	50Vdc	3300pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H332K0□□H03□	X7R (EIA)	50Vdc	3300pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H472K0□□H03□	X7R (EIA)	50Vdc	4700pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H472K0□□H03□	X7R (EIA)	50Vdc	4700pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H682K0□□H03□	X7R (EIA)	50Vdc	6800pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H682K0□□H03□	X7R (EIA)	50Vdc	6800pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H103K0□□H03□	X7R (EIA)	50Vdc	10000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H103K0□□H03□	X7R (EIA)	50Vdc	10000pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H153K0□□H03□	X7R (EIA)	50Vdc	15000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H153K0□□H03□	X7R (EIA)	50Vdc	15000pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H223K0□□H03□	X7R (EIA)	50Vdc	22000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H223K0□□H03□	X7R (EIA)	50Vdc	22000pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H333K0□□H03□	X7R (EIA)	50Vdc	33000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H333K0□□H03□	X7R (EIA)	50Vdc	33000pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H473K0□□H03□	X7R (EIA)	50Vdc	47000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H473K0□□H03□	X7R (EIA)	50Vdc	47000pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H683K0□□H03□	X7R (EIA)	50Vdc	68000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H683K0□□H03□	X7R (EIA)	50Vdc	68000pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H104K0□□H03□	X7R (EIA)	50Vdc	0.1µF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER71H104K0□□H03□	X7R (EIA)	50Vdc	0.1µF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER71H154K1□□H03□	X7R (EIA)	50Vdc	0.15µF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER71H154K1□□H03□	X7R (EIA)	50Vdc	0.15µF±10%	5.0×3.5	3.15	2.5	P1	S1
RDER71H224K1□□H03□	X7R (EIA)	50Vdc	0.22µF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER71H224K1□□H03□	X7R (EIA)	50Vdc	0.22μF±10%	5.0×3.5	3.15	2.5	P1	S1

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RDER71H334K1□□H03□	X7R (EIA)	50Vdc	0.33µF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER71H334K1□□H03□	X7R (EIA)	50Vdc	0.33µF±10%	5.0×3.5	3.15	2.5	P1	S1
RDER71H474K1□□H03□	X7R (EIA)	50Vdc	0.47µF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER71H474K1□□H03□	X7R (EIA)	50Vdc	0.47µF±10%	5.0×3.5	3.15	2.5	P1	S1
RDER71H684K2□□H03□	X7R (EIA)	50Vdc	0.68µF±10%	5.5×4.0	3.15	2.5	P1	S1
RDER71H684K2□□H03□	X7R (EIA)	50Vdc	0.68µF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER71H105K2□□H03□	X7R (EIA)	50Vdc	1.0µF±10%	5.5×4.0	3.15	2.5	P1	S1
RDER71H105K2□□H03□	X7R (EIA)	50Vdc	1.0µF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER71H155K2□□H03□	X7R (EIA)	50Vdc	1.5µF±10%	5.5×4.0	3.15	2.5	P1	S1
RDER71H155K2□□H03□	X7R (EIA)	50Vdc	1.5µF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER71H225K2□□H03□	X7R (EIA)	50Vdc	2.2µF±10%	5.5×4.0	3.15	2.5	P1	S1
RDER71H225K2□□H03□	X7R (EIA)	50Vdc	2.2µF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER71H335K3□□H03□	X7R (EIA)	50Vdc	3.3µF±10%	5.5×5.0	4.0	2.5	P1	S1
RDER71H335K3□□H03□	X7R (EIA)	50Vdc	3.3µF±10%	5.5×5.0	4.0	5.0	K1	M1
RDEC71H475K2□□H03□	X7S (EIA)	50Vdc	4.7μF±10%	5.5×4.0	3.15	2.5	P1	S1
RDEC71H475K2□□H03□	X7S (EIA)	50Vdc	4.7μF±10%	5.5×4.0	3.15	5.0	K1	M1
RDEC71H106K3□□H03□	X7S (EIA)	50Vdc	10μF±10%	5.5×5.0	4.0	2.5	P1	S1
RDEC71H106K3□□H03□	X7S (EIA)	50Vdc	10μF±10%	5.5×5.0	4.0	5.0	K1	M1
RDEC71H226MW□□H03□	X7S (EIA)	50Vdc	22µF±20%	5.5×7.5	4.0	5.0	K1	M1
RDER72A221K0□□H03□	X7R (EIA)	100Vdc	220pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER72A221K0□□H03□	X7R (EIA)	100Vdc	220pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER72A331K0□□H03□	X7R (EIA)	100Vdc	330pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER72A331K0□□H03□	X7R (EIA)	100Vdc	330pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER72A471K0□□H03□	X7R (EIA)	100Vdc	470pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER72A471K0□□H03□	X7R (EIA)	100Vdc	470pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER72A681K0□□H03□	X7R (EIA)	100Vdc	680pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER72A681K0□□H03□	X7R (EIA)	100Vdc	680pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER72A102K0□□H03□	X7R (EIA)	100Vdc	1000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER72A102K0□□H03□	X7R (EIA)	100Vdc	1000pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER72A152K0□□H03□	X7R (EIA)	100Vdc	1500pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER72A152K0□□H03□	X7R (EIA)	100Vdc	1500pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER72A222K0□□H03□	X7R (EIA)	100Vdc	2200pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER72A222K0 H03	X7R (EIA)	100Vdc	2200pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER72A332K0 H03	X7R (EIA)	100Vdc	3300pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER72A332K0 H03	X7R (EIA)	100Vdc	3300pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER72A472K0 H03	X7R (EIA)	100Vdc	4700pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER72A472K0 H03	X7R (EIA)	100Vdc	4700pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER72A682K0 H03	X7R (EIA)	100Vdc	6800pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER72A682K0 H03	X7R (EIA)	100Vdc	6800pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER72A103K0 H03	X7R (EIA)	100Vdc	10000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER72A103K0□□H03□ RDER72A153K0□□H03□	X7R (EIA)	100Vdc 100Vdc	10000pF±10% 15000pF±10%	5.0×3.5 4.0×3.5	2.5	2.5 5.0	P1 K1	S1 M1
RDER72A153K0	X7R (EIA) X7R (EIA)	100 Vdc	15000pF±10% 15000pF±10%	4.0×3.5 5.0×3.5	2.5	2.5	P1	S1
RDER72A193K0 H03 RDER72A223K0 H03	X7R (EIA)	100Vdc	22000pF±10%	4.0×3.5	2.5	5.0	K1	M1
RDER72A223K0 - H03	X7R (EIA)	100Vdc	22000pF±10% 22000pF±10%	5.0×3.5	2.5	2.5	P1	S1
RDER72A333K1 H03	X7R (EIA)	100Vdc	33000pF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72A333K1 H03	X7R (EIA)	100Vdc	33000pF±10%	5.0×3.5	3.15	2.5	P1	S1
RDER72A473K1 H03	X7R (EIA)	100Vdc	47000pF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72A473K1 H03	X7R (EIA)	100Vdc	47000pF±10%	5.0×3.5	3.15	2.5	P1	S1
RDER72A683K1 H03	X7R (EIA)	100Vdc	68000pF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72A683K1 H03	X7R (EIA)	100Vdc	68000pF±10%	5.0×3.5	3.15	2.5	P1	S1
RDER72A104K1 H03	X7R (EIA)	100Vdc	0.1μF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72A104K1□□H03□	X7R (EIA)	100Vdc	0.1µF±10%	5.0×3.5	3.15	2.5	P1	S1
RDER72A154K2 H03	X7R (EIA)	100Vdc	0.15µF±10%	5.5×4.0	3.15	2.5	P1	S1
RDER72A154K2 H03	X7R (EIA)	100Vdc	0.15µF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72A224K1 H03	X7R (EIA)	100Vdc	0.22μF±10%	4.5×3.5	3.15	5.0	K1	M1
		100Vdc	0.22μF±10%	5.0×3.5	3.15	2.5	P1	S1

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RDER72A334K1□□H03□	X7R (EIA)	100Vdc	0.33µF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72A334K1□□H03□	X7R (EIA)	100Vdc	0.33µF±10%	5.0×3.5	3.15	2.5	P1	S1
RDER72A474K1□□H03□	X7R (EIA)	100Vdc	0.47µF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72A474K1□□H03□	X7R (EIA)	100Vdc	0.47µF±10%	5.0×3.5	3.15	2.5	P1	S1
RDER72A684K2□□H03□	X7R (EIA)	100Vdc	0.68µF±10%	5.5×4.0	3.15	2.5	P1	S1
RDER72A684K2□□H03□	X7R (EIA)	100Vdc	0.68µF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72A105K2□□H03□	X7R (EIA)	100Vdc	1.0µF±10%	5.5×4.0	3.15	2.5	P1	S1
RDER72A105K2□□H03□	X7R (EIA)	100Vdc	1.0µF±10%	5.5×4.0	3.15	5.0	K1	M1
RDEC72A155K3□□H03□	X7S (EIA)	100Vdc	1.5µF±10%	5.5×5.0	4.0	2.5	P1	S1
RDEC72A155K3□□H03□	X7S (EIA)	100Vdc	1.5µF±10%	5.5×5.0	4.0	5.0	K1	M1
RDEC72A225K3□□H03□	X7S (EIA)	100Vdc	2.2µF±10%	5.5×5.0	4.0	2.5	P1	S1
RDEC72A225K3□□H03□	X7S (EIA)	100Vdc	2.2µF±10%	5.5×5.0	4.0	5.0	K1	M1
RDEC72A475MW□□H03□	X7S (EIA)	100Vdc	4.7µF±20%	5.5×7.5	4.0	5.0	K1	M1
RDER72E102K1□□H03□	X7R (EIA)	250Vdc	1000pF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72E152K1□□H03□	X7R (EIA)	250Vdc	1500pF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72E222K1□□H03□	X7R (EIA)	250Vdc	2200pF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72E332K1□□H03□	X7R (EIA)	250Vdc	3300pF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72E472K1□□H03□	X7R (EIA)	250Vdc	4700pF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72E682K1□□H03□	X7R (EIA)	250Vdc	6800pF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72E103K1□□H03□	X7R (EIA)	250Vdc	10000pF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72E153K1□□H03□	X7R (EIA)	250Vdc	15000pF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72E223K1□□H03□	X7R (EIA)	250Vdc	22000pF±10%	4.5×3.5	3.15	5.0	K1	M1
RDER72E333K2□□H03□	X7R (EIA)	250Vdc	33000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72E473K2□□H03□	X7R (EIA)	250Vdc	47000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72E683K2□□H03□	X7R (EIA)	250Vdc	68000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72E104K2□□H03□	X7R (EIA)	250Vdc	0.10µF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72E154K3□□H03□	X7R (EIA)	250Vdc	0.15µF±10%	5.5×5.0	3.15	5.0	K1	M1
RDER72E224K3□□H03□	X7R (EIA)	250Vdc	0.22µF±10%	5.5×5.0	3.15	5.0	K1	M1
RDER72E334K4□□H03□	X7R (EIA)	250Vdc	0.33µF±10%	7.5×5.5	4.0	5.0	K1	M1
RDER72E474K4□□H03□	X7R (EIA)	250Vdc	0.47µF±10%	7.5×5.5	4.0	5.0	K1	M1
RDER72E684K5□□H03□	X7R (EIA)	250Vdc	0.68µF±10%	7.5×7.5	4.0	5.0	B1	E1
RDER72E105K5□□H03□	X7R (EIA)	250Vdc	1.0µF±10%	7.5×7.5	4.0	5.0	B1	E1
RDER72E225MU□□H03□	X7R (EIA)	250Vdc	2.2µF±20%	7.7×12.5	4.0	5.0	B1	E1
RDER72J102K2□□H03□	X7R (EIA)	630Vdc	1000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72J152K2□□H03□	X7R (EIA)	630Vdc	1500pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72J222K2□□H03□	X7R (EIA)	630Vdc	2200pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72J332K2□□H03□	X7R (EIA)	630Vdc	3300pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72J472K2□□H03□	X7R (EIA)	630Vdc	4700pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72J682K2□□H03□	X7R (EIA)	630Vdc	6800pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72J103K2□□H03□	X7R (EIA)	630Vdc	10000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72J153K2□□H03□	X7R (EIA)	630Vdc	15000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72J223K2□□H03□	X7R (EIA)	630Vdc	22000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER72J333K3□□H03□	X7R (EIA)	630Vdc	33000pF±10%	5.5×5.0	3.15	5.0	K1	M1
RDER72J473K3□□H03□	X7R (EIA)	630Vdc	47000pF±10%	5.5×5.0	3.15	5.0	K1	M1
RDER72J683K4□□H03□	X7R (EIA)	630Vdc	68000pF±10%	7.5×5.5	3.15	5.0	K1	M1
RDER72J104K4□□H03□	X7R (EIA)	630Vdc	0.10µF±10%	7.5×5.5	3.15	5.0	K1	M1
RDER72J154K5□□H03□	X7R (EIA)	630Vdc	0.15µF±10%	7.5×8.0	4.0	5.0	B1	E1
RDER72J224K5□□H03□	X7R (EIA)	630Vdc	0.22µF±10%	7.5×8.0	4.0	5.0	B1	E1
RDER72J474MU□□H03□	X7R (EIA)	630Vdc	0.47µF±20%	7.7×13.0	4.0	5.0	B1	E1
RDER73A471K2□□H03□	X7R (EIA)	1000Vdc	470pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER73A681K2□□H03□	X7R (EIA)	1000Vdc	680pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER73A102K2□□H03□	X7R (EIA)	1000Vdc	1000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER73A152K2□□H03□	X7R (EIA)	1000Vdc	1500pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER73A222K2□□H03□	X7R (EIA)	1000Vdc	2200pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER73A332K2□□H03□	X7R (EIA)	1000Vdc	3300pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER73A472K2□□H03□	X7R (EIA)	1000Vdc	4700pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER73A682K2□□H03□	X7R (EIA)	1000Vdc	6800pF±10%	5.5×4.0	3.15	5.0	K1	M1

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RDER73A103K2□□H03□	X7R (EIA)	1000Vdc	10000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDER73A153K3□□H03□	X7R (EIA)	1000Vdc	15000pF±10%	5.5×5.0	4.0	5.0	K1	M1
RDER73A223K3□□H03□	X7R (EIA)	1000Vdc	22000pF±10%	5.5×5.0	4.0	5.0	K1	M1
RDER73A333K4□□H03□	X7R (EIA)	1000Vdc	33000pF±10%	7.5×5.5	4.0	5.0	K1	M1
RDER73A473K4□□H03□	X7R (EIA)	1000Vdc	47000pF±10%	7.5×5.5	4.0	5.0	K1	M1
RDER73A683K5□□H03□	X7R (EIA)	1000Vdc	68000pF±10%	7.5×8.0	4.0	5.0	B1	E1
RDER73A104K5□□H03□	X7R (EIA)	1000Vdc	0.10µF±10%	7.5×8.0	4.0	5.0	B1	E1
RDER73A224MU□□H03□	X7R (EIA)	1000Vdc	0.22µF±20%	7.7×13.0	4.0	5.0	B1	E1

Two blank columns are filled with the lead style code. Please refer to the 3 columns on the right for the appropriate code.

High Dielectric Constant Type, F/Y5V Characteristics

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RDEF11H103Z0□□H01□	F (JIS)	50Vdc	10000pF+80/-20%	4.0×3.5	2.5	5.0	K1	M1
RDEF11H103Z0□□H01□	F (JIS)	50Vdc	10000pF+80/-20%	5.0×3.5	2.5	2.5	P1	S1
RDEF51H103Z0□□H03□	Y5V (EIA)	50Vdc	10000pF+80/-20%	4.0×3.5	2.5	5.0	K1	M1
RDEF51H103Z0□□H03□	Y5V (EIA)	50Vdc	10000pF+80/-20%	5.0×3.5	2.5	2.5	P1	S1
RDEF11H223Z0□□H01□	F (JIS)	50Vdc	22000pF+80/-20%	4.0×3.5	2.5	5.0	K1	M1
RDEF11H223Z0□□H01□	F (JIS)	50Vdc	22000pF+80/-20%	5.0×3.5	2.5	2.5	P1	S1
RDEF51H223Z0□□H03□	Y5V (EIA)	50Vdc	22000pF+80/-20%	4.0×3.5	2.5	5.0	K1	M1
RDEF51H223Z0□□H03□	Y5V (EIA)	50Vdc	22000pF+80/-20%	5.0×3.5	2.5	2.5	P1	S1
RDEF11H473Z0□□H01□	F (JIS)	50Vdc	47000pF+80/-20%	4.0×3.5	2.5	5.0	K1	M1
RDEF11H473Z0□□H01□	F (JIS)	50Vdc	47000pF+80/-20%	5.0×3.5	2.5	2.5	P1	S1
RDEF51H473Z0□□H03□	Y5V (EIA)	50Vdc	47000pF+80/-20%	4.0×3.5	2.5	5.0	K1	M1
RDEF51H473Z0□□H03□	Y5V (EIA)	50Vdc	47000pF+80/-20%	5.0×3.5	2.5	2.5	P1	S1
RDEF11H104Z0□□H01□	F (JIS)	50Vdc	0.1µF+80/-20%	4.0×3.5	2.5	5.0	K1	M1
RDEF11H104Z0□□H01□	F (JIS)	50Vdc	0.1µF+80/-20%	5.0×3.5	2.5	2.5	P1	S1
RDEF51H104Z0□□H03□	Y5V (EIA)	50Vdc	0.1µF+80/-20%	4.0×3.5	2.5	5.0	K1	M1
RDEF51H104Z0□□H03□	Y5V (EIA)	50Vdc	0.1µF+80/-20%	5.0×3.5	2.5	2.5	P1	S1

Two blank columns are filled with the lead style code. Please refer to the 3 columns on the right for the appropriate code.

The last blank column is filled with the packaging code. (B: bulk, A: ammo pack)

The last blank column is filled with the packaging code. (B: bulk, A: ammo pack)

NI.	,		Specifi	cations		Tank Matter 1			
No.	Ite	11	Temperature Compensating Type	High Dielectric Constant Type		Test Method			
1	Operating Ter Range	nperature	-55 to +125°C	Char. X7R, X7S: -55 to +125°C Char. F: -25 to +85°C Char. Y5V: -30 to +85°C		-			
2	Appearance		No defects or abnormalities		Visual inspection				
3	Dimension an	d Marking	See previous pages		Visual inspection, V	ernier Caliper			
	Dielectric	Between Terminals	No defects or abnormalities		Temperature DC50 Compensating DC20 Type DC60 DC11 High Dielectric DC20	re applied betwee rge/Discharge cu ed Voltage 00V, DC100V 3009 3009 3000 1509 300	en the terminals		
4	Strength	Body Insulation	No defects or abnormalities		The capacitor is placed in a container with metal balls of 1mm diameter so that each terminal, short-circuited, is kept approximately 2mm from the balls as shown in the figure, for 1 to 5 sec. between capacitor terminals and metal balls. (Charge/Discharge current ≤ 50mA) Rated Voltage Test Voltage DC25V, DC50V 250% of the rated voltage DC130V, DC250V DC1300V DC1300V				
5	Insulation Resistance	Between Terminals	Rated Voltage: DC25V, DC50V, 10,000MΩ min. or 500MΩ • μF Rated Voltage: DC250V, DC630 10,000MΩ min. or 100MΩ • μF	The insulation resistance should be measured with a DC voltage not exceeding the rated voltage (DC500±50V in case of rated vlotage: DC630V, DC1kV) at normal temperature and humidity and within 2 min. of charging. (Charge/Discharge current ≤ 50mA)					
6	Capacitance		Within the specified tolerance		The capacitance, Q				
7	Q/Dissipation Factor (D.F.) 30pF max.: Q≥400+20C Char.		Char. X7R: 0.025 max. Char. F, Y5V: 0.05 max. Char. X7S: 0.125 max.	Temperature Comp Capacitance Item Frequency Voltage High Dielectric Con Capacitance Item Frequency Voltage	C≦1000pF 1±0.1MHz AC0.5 to 5V (r.m.s.)	C>1000pF 1±0.1kHz AC1±0.2V (r.m.s.) C>10µF 120±24Hz AC0.5±0.1V (r.m.s.)			

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The capacitance change should be measured after 5 min. at each specified temperature stage. (1) Temperature Compensating Type The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5 (-55 to +125°C) the capacitance should be within the specified tolerance for the temperature coefficient and capacitance change as shown in Table A. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in step 1, 3 and 5 by the cap. value in step 3. Step Temperature (°C)
min. at each specified temperature stage. (1) Temperature Compensating Type The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5 (-55 to +125°C) the capacitance should be within the specified tolerance for the temperature coefficient and capacitance change as shown in Table A. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in step 1, 3 and 5 by the cap. value in step 3. Step Temperature (°C)
coefficient and capacitance change as shown in Table A. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in step 1, 3 and 5 by the cap. value in step 3. Step Temperature (°C) 1
3 25±2 4 125±3 5 25±2 (2) High Dielectric Constant Type The ranges of capacitance change compared with the 25°C (Char. F: 20°C) value over the temperature ranges as shown in Table B should be within the specified ranges. • Pretreatment (for high dielectric constant type) Perform a heat treatment at 150+0/-10°C for 1 hr., and
25°C (Char. F: 20°C) value over the temperature ranges as shown in Table B should be within the specified ranges. • Pretreatment (for high dielectric constant type) Perform a heat treatment at 150+0/-10°C for 1 hr., and
As in the figure, fix the capacitor body, apply the force gradually to each lead in the radial direction of the capacitor until reaching 10N and then keep the force applied for 10±1 sec.
Each lead wire should be subjected to a force of 2.5N and then bent 90° at the point of egress in one direction. Each wire is then returned to the original position and bent 90° in the opposite direction at the rate of one bend per 2 to 3 sec.
The capacitor is soldered securely to a supporting
terminal and a 10 to 55Hz vibration of 1.5mm peak-peak amplitude is applied for 6 hrs. total, 2 hrs. in each mutually perpendicular direction. Allow 1 min. to cycle the frequency from 10Hz to 55Hz and the converse.
The terminal of a capacitor is dipped into a 25% ethanol (JIS-K-8101) solution of rosin (JIS-K-5902) and then into molten solder for 2±0.5 sec. In both cases the depth of dipping is up to about 1.5mm to 2mm from the terminal body. Temp. of solder: 245±5°C Lead Free Solder (Sn-3.0Ag-0.5Cu) 235±5°C H60A or H63A Eutectic Solder
The lead wire is immersed in the melted solder 1.5mm
Vithin ±10% to 2mm from the main body at 350±10°C for 3.5±0.5 in ±20% sec.
The specified items are measured after 24±2 hrs. • Pretreatment (for high dielectric constant type) Perform a heat treatment at 150+0/-10°C for 1 hr., and then let sit at room temperature for 24±2 hrs.

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No.	Ite	m	Specifi	cations		Test Meth	nod	
١٠.	1101	11	Temperature Compensating Type	High Dielectric Constant Type		rest ivieti	iou	
		Appearance	No defects or abnormalities					
		Capacitance Change	Within ±5% or ±0.5pF (whichever is larger)	Char. X7R, X7S: Within ±12.5% Char. F, Y5V: Within ±30%	The capacito cycles.	or should be subject	cted to 5 to	emperature
		Q/D.F.	30pF min.: Q≥350 10pF to 30pF: Q≥275+5C/2 10pF max.: Q≥200+10C	Char. X7R: 0.05 max. Char. F, Y5V: 0.075 max. Char. X7S: 0.2 max.	Remove and then measur	I set for 24±2 hrs. e. Temperature		
	Temperature		C: Nominal capacitance (pF)	Olidi. A73. 0.2 iliax.	Step 1	Min. Operating Te		Time (min) 30±3
13	Cycle	Insulation Resistance	Rated Voltage: DC25V, DC50V, 1,000MΩ, 50MΩ • μF min. (wh Rated Voltage: DC250V, DC630 1,000MΩ, 10MΩ • μF min. (wh	nichever is smaller) V	2 3 4	Room Tem Max. Operating To Room Tem	p. emp. ±3 p.	3 max. 30±3 3 max.
		Dielectric Strength (Between Terminals)	No defects or abnormalities		Pretreatment (for high dielectric constant type) Perform a heat treatment at 150+0/-10°C for 1 hr., then let sit at room temperature for 24±2 hrs.			for 1 hr., and
		Appearance	No defects or abnormalities					
		Capacitance Change	Within ±5% or ±0.5pF (whichever is larger)	Char. X7R, X7S: Within ±15% Char. F, Y5V: Within ±30%		icitor at 40±2°C an	nd relative	humidity of
14	Humidity (Steady State)	Q/D.F.	30pF min.: Q≥350 10pF to 30pF: Q≥275+5C/2 10pF max.: Q≥200+10C C: Nominal capacitance (pF)	Char. X7R: 0.05 max. Char. F, Y5V: 0.075 max. Char. X7S: 0.2 max.	90 to 95% for 500±2d hrs. Remove and set for 24±2 hrs. at room temperature, then measure. • Pretreatment (for high dielectric constant type)			
	Insulation Resistance		Rated Voltage: DC25V, DC50V, 1,000MΩ, 50MΩ • μF min. (wh Rated Voltage: DC250V, DC630 1,000MΩ, 10MΩ • μF min. (wh	nichever is smaller) V		eat treatment at 15 t room temperature		
		Appearance	No defects or abnormalities					
		Capacitance Change	Within ±7.5% or ±0.75pF (whichever is larger)	Char. X7R, X7S: Within ±15% Char. F, Y5V: Within ±30%	Apply the rated voltage for 500 ^{±2} / ₀ hrs. at 40±2°C a in 90 to 95% humidity.			t 40±2°C and
15	Humidity Load	Q/D.F.	30pF min.: Q≧200 30pF max.: Q≧100+10C/3 C: Nominal capacitance (pF)	Char. X7R: 0.05 max. Char. F, Y5V: 0.075 max. Char. X7S: 0.2 max.	then measur (Charge/Disc	charge current ≦50	0mA)	
		Insulation Resistance	Rated Voltage: DC25V, DC50V, 500MΩ or 25MΩ • μF min. (wh Rated Voltage: DC250V, DC630 1,000MΩ or 10MΩ • μF min. (v	nichever is smaller) V	 Pretreatment (for high dielectric constant type) Perform a heat treatment at 150+0/-10°C for 1 hr., and then let sit at room temperature for 24±2 hrs. 			
		Appearance	No defects or abnormalities		Apply voltage	e in Table for 1000	0 ⁺⁴⁸ hrs. a	at the
		Capacitance	Within ±3% or ±0.3pF	Char. X7R, X7S: Within ±15% (Rated Voltage: DC630V or less)	Remove and	perating temperatu I set for 24±2 hrs. re. (Charge/Discha	at room te	•
	High	Change	(whichever is larger)	Within ±20% (Rated Voltage: DC1kV) Char. F, Y5V: Within ±30%	Temperature Compensating	Rated Voltage DC50V, DC100V, DC250V		Voltage rated voltage
16	Temperature Load	Q/D.F.	30pF min.: Q≥350 10pF to 30pF: Q≥275+5C/2 10pF max.: Q≥200+10C C: Nominal capacitance (pF)	Char. X7R: 0.05 max. Char. F, Y5V: 0.075 max. Char. X7S: 0.2 max.	Type High Dielectric Constant Type	DC630V, DC1kV DC25V, DC50V, DC100V, DC250V DC630V	150% of the	e rated voltage e rated voltage e rated voltage
		Insulation Resistance	Rated Voltage: DC25V, DC50V, 1,000MΩ, 50MΩ • μF min. (wh Rated Voltage: DC250V, DC630 1,000MΩ, 10MΩ • μF min. (wh	nichever is smaller) V	Appy test vol	DC1kV nt (for high dielect Itage for 1 hr., at te I set for 24±2 hrs.	ric constar est temper	ature.
		Appearance	No defects or abnormalities			or should be fully in		
17	Solvent Resistance	Marking	Legible	reagent at 20 to 25°C for 30±5 sec. and then removed gently. Marking on the surface of the capacitor should immediately be visually examined. Reagent: • Isopropyl alcohol				

Table A

Char.	Nominal Values	Capacitance Change from 25°C (%)								
		−55°C		−30°C		−10°C				
	(ppm/°C) *1	Max.	Min.	Max.	Min.	Max.	Min.			
COG	0±30	0.58	-0.24	0.40	-0.17	0.25	-0.11			
U2J	-750±120	8.78	5.04	6.04	3.47	3.84	2.21			

^{*1:} Nominal values denote the temperature coefficient within a range of 25 to 125°C

Table B

Char.	Temp. Range	Reference Temp.	Cap. Change Rate	
X7R	–55 to +125°C		Within ±15%	
X7S	-33 t0 +123 C	25°C	Within ±22%	
Y5V	-30 to + 85°C		Within ±8월%	
F	-25 to + 85°C	20°C	Within ±30%	



Radial Lead Type Monolithic Ceramic Capacitors



RDE Series Large Capacitance and High Allowable Ripple Current (For General Use Only) (DC250V-DC630V)

■ Features

- 1. Higher capacitance with DC-Bias; approximately 40% higher than X7R under loaded rated voltage.
- 2. Meet LF (Lead Free) and HF (Halogen Free)
- 3. Allowable higher ripple current
- Reduces acoustic noise
 Approximately 15dB reduction in comparison to leaded X7R characteristics parts.

Approximately 30dB reduction in comparison to SMD X7R characteristics part because the contact area is smaller than a SMD.

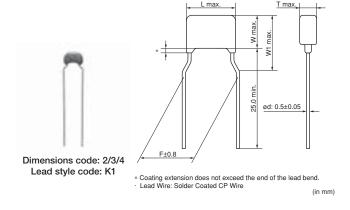
Applications

- 1. DC smoothing capacitor for LED bulb
- 2. PFC capacitor for general use SMPS
- 3. Replace Al-E capacitor for long-life equipment

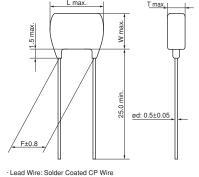
Dimensions

Dimensions and		Dimensions (mm)						
Lead Style Code	Voltage	L	W	W1	Т	F	d	
2K1/2M1	250V/450V/630V	5.5	4.0	6.0		5.0	0.5	
3K1/3M1	250V/450V/630V	5.5	5.0	7.5	See	5.0	0.5	
4K1/4M1	250V/450V/630V	7.5	5.5	8.0	the individual product	5.0	0.5	
5B1/5E1	250V/450V/630V	7.5	7.5*	-	specification	5.0	0.5	
UB1/UE1	250V/450V/630V	7.7	12.5*	-		5.0	0.5	

^{*}DC630V: W+0.5mm

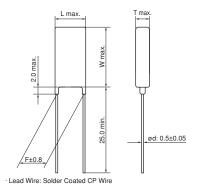






(in mm)





(in mm)

■ Marking

	Rated Voltage	DC250V	DC450V	DC630V			
Dimensions Code	Temp. Char.		X7T				
	2	(M 683)	(M 153 K97	(M 153)			
	3, 8	(M 334 K47	M 104 K97	(M 223 K77			
	5, U	②M 225 M47	(M) 474 K97	(M) 474 M77			
Temperatur	e Characteristics	Marked with code (X7T char.: 7)					
Nominal	Capacitance	Marked with 3 figures					
Capacita	nce Tolerance	Marked with code					
Rate	d Voltage	Marked with code (DC250V: 4, DC450V: 9, DC630V: 7)					
Manufacture	er's Identification	Marked with (M					

High Dielectric Constant Type, X7T Characteristics

Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RDED72E333K2□□H03□	X7T (EIA)	250Vdc	33000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDED72E473K2□□H03□	X7T (EIA)	250Vdc	47000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDED72E683K2□□H03□	X7T (EIA)	250Vdc	68000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDED72E104K3□□H03□	X7T (EIA)	250Vdc	0.10µF±10%	5.5×5.0	4.0	5.0	K1	M1
RDED72E154K3□□H03□	X7T (EIA)	250Vdc	0.15µF±10%	5.5×5.0	4.0	5.0	K1	M1
RDED72E224K4□□H03□	X7T (EIA)	250Vdc	0.22µF±10%	7.5×5.5	4.0	5.0	K1	M1
RDED72E334K4□□H03□	X7T (EIA)	250Vdc	0.33µF±10%	7.5×5.5	4.0	5.0	K1	M1
RDED72E474K5□□H03□	X7T (EIA)	250Vdc	0.47µF±10%	7.5×7.5	4.5	5.0	B1	E1
RDED72E684K5□□H03□	X7T (EIA)	250Vdc	0.68µF±10%	7.5×7.5	4.5	5.0	B1	E1
RDED72E105K5□□H03□	X7T (EIA)	250Vdc	1.0µF±10%	7.5×7.5	4.5	5.0	B1	E1
RDED72E225MU□□H03□	X7T (EIA)	250Vdc	2.2µF±20%	7.7×12.5	4.5	5.0	B1	E1
RDED72W103K2□□H03□	X7T (EIA)	450Vdc	10000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDED72W153K2□□H03□	X7T (EIA)	450Vdc	15000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDED72W223K2□□H03□	X7T (EIA)	450Vdc	22000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDED72W333K2□□H03□	X7T (EIA)	450Vdc	33000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDED72W473K2□□H03□	X7T (EIA)	450Vdc	47000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDED72W683K3□□H03□	X7T (EIA)	450Vdc	68000pF±10%	5.5×5.0	4.0	5.0	K1	M1
RDED72W104K3□□H03□	X7T (EIA)	450Vdc	0.10µF±10%	5.5×5.0	4.0	5.0	K1	M1
RDED72W154K4□□H03□	X7T (EIA)	450Vdc	0.15µF±10%	7.5×5.5	4.0	5.0	K1	M1
RDED72W224K5□□H03□	X7T (EIA)	450Vdc	0.22µF±10%	7.5×7.5	4.5	5.0	B1	E1
RDED72W334K5□□H03□	X7T (EIA)	450Vdc	0.33µF±10%	7.5×7.5	4.5	5.0	B1	E1
RDED72W474K5□□H03□	X7T (EIA)	450Vdc	0.47µF±10%	7.5×7.5	4.5	5.0	B1	E1
RDED72W564K5□□H03□	X7T (EIA)	450Vdc	0.56µF±10%	7.5×7.5	4.5	5.0	B1	E1
RDED72W105MU□□H03□	X7T (EIA)	450Vdc	1.0µF±20%	7.7×12.5	4.5	5.0	B1	E1
RDED72W125MU□□H03□	X7T (EIA)	450Vdc	1.2µF±20%	7.7×12.5	4.5	5.0	B1	E1
RDED72J103K2□□H03□	X7T (EIA)	630Vdc	10000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDED72J153K2□□H03□	X7T (EIA)	630Vdc	15000pF±10%	5.5×4.0	3.15	5.0	K1	M1
RDED72J223K3□□H03□	X7T (EIA)	630Vdc	22000pF±10%	5.5×5.0	4.0	5.0	K1	M1
RDED72J333K3□□H03□	X7T (EIA)	630Vdc	33000pF±10%	5.5×5.0	4.0	5.0	K1	M1
RDED72J473K3□□H03□	X7T (EIA)	630Vdc	47000pF±10%	5.5×5.0	4.0	5.0	K1	M1
RDED72J683K4□□H03□	X7T (EIA)	630Vdc	68000pF±10%	7.5×5.5	4.0	5.0	K1	M1
RDED72J104K5□□H03□	X7T (EIA)	630Vdc	0.10µF±10%	7.5×8.0	4.5	5.0	B1	E1
RDED72J154K5□□H03□	X7T (EIA)	630Vdc	0.15µF±10%	7.5×8.0	4.5	5.0	B1	E1
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Part Number	Temp. Char.	Rated Voltage	Capacitance	Dimensions LxW (mm)	Dimension T (mm)	Lead Space F (mm)	Lead Style Code Bulk	Lead Style Code Taping
RDED72J224K5□□H03□	X7T (EIA)	630Vdc	0.22µF±10%	7.5×8.0	4.5	5.0	B1	E1
RDED72J274K5□□H03□	X7T (EIA)	630Vdc	0.27µF±10%	7.5×8.0	4.5	5.0	B1	E1
RDED72J474MU□□H03□	X7T (EIA)	630Vdc	0.47µF±20%	7.7×13.0	4.5	5.0	B1	E1
RDED72J564MU□□H03□	X7T (EIA)	630Vdc	0.56µF±20%	7.7×13.0	4.5	5.0	B1	E1

Two blank columns are filled with the lead style code. Please refer to the 3 columns on the right for the appropriate code.

The last blank column is filled with the packaging code. (B: bulk, A: ammo pack)

No.	Ite	m	Specifications		Test Method
1	Operating Ter Range	nperature	-55 to +125°C		_
2	Appearance		No defects or abnormalities	Visual inspection	
3	Dimension an	d Marking	See previous pages	Visual inspection,	Vernier Caliper
	Between Terminals		No defects or abnormalities		ld not be damaged when voltage between the terminations current ≤ 50mA) Test Voltage 200% of the rated voltage 150% of the rated voltage 120% of the rated voltage
4	Dielectric Strength	Body Insulation	No defects or abnormalities	The capacitor is placed in a container with metal balls of 1mm diameter so that each terminal, short-circuit, is kept approximately 2mm from the balls as shown in	
5	Insulation Resistance	Between Terminals	More than 10,000M Ω or 100M $\Omega \cdot \mu F$, Whichever is smaller	The insulation resistance should be measured with DC500±50V (DC250±25V in case of rated voltage: DC250V,DC450V) at normal temperature and hum and within 2 min. of charging. (Charge/Discharge current ≤ 50mA)	
6	Capacitance		Within the specified tolerance	The capacitance/D.F. should be measured at the	
7	Dissipation Fa	actor (D.F.)	0.01 max.	frequency of 1±0.1kHz and a voltage of AC1±0.2V(r.m.s.).	
				The capacitance change should be measured after 5 min. at each specified temperature stage.	
	Capacitance	nperature Within +22/-33%		Step	Temperature (°C)
8	Temperature			1	25±2 -55±3
	Characteristic			3	25±2
				4	125±3
				5	25±2
9	Terminal Strength	Tensile Strength	Termination not to be broken or loosened	As in the figure, fix the capacitor body, apply the gradually to each lead in the radial direction of the capacitor until reaching 10N and then keep the applied for 10±1 sec. Each lead wire should be subjected to a force of and then bent 90° at the point of egress in one direction. Each wire is then returned to the origing position and bent 90° in the opposite direction are rate of one bend per 2 to 3 sec.	
		Bending Strength	Termination not to be broken or loosened		
		Appearance	No defects or abnormalities		uld be firmly soldered to the
	Vibration	Capacitance	Within the specified tolerance		re and vibrated at a frequency range mm in total amplitude, with about a 1
10	Resistance	D.F.	0.01 max.	minute rate of vibra	ation change from 10Hz to 55Hz and y for a total of 6 hrs., 2 hrs. each in 3

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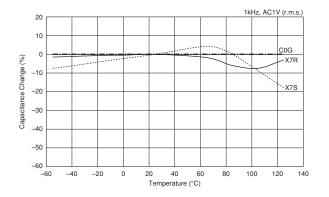
\(\) Continued from the preceding page.

No.	Iter	n	Specifications		Т	est Method	
11	Solderability o	f Leads	Lead wire should be soldered with uniform coating on the axial direction over 3/4 of the circumferential direction.	The terminal of a capacitor is dipped into a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin weight proportion) and then into molten solder (JIS Z-3282) for 2±0.5 sec. In both cases the depth of dipping is up to about 1.5 to 2mm from the terminal body. Temp. of solder: 245±5°C Lead Free Solder (Sn-3.0Ag-0.50 235±5°C H60A or H63A Eutectic Solder			K-5902) (25% rosin lolten solder (JIS- the depth of the terminal der (Sn-3.0Ag-0.5Cu)
		Appearance	No defects or abnormalities	The leadership		and the Marketine	
	Resistance to	Capacitance Change	Within ±10%	2mm from the	e main bo		Ited solder 1.5 to C for 3.5±0.5 sec. Iter 24±2 hrs.
12	Soldering Heat	Dielectric Strength (Between Terminals)	No defects	• Pretreatment Perform a heat treatment at 150+0/-10°C for 1 hr., at then let sit at room temperature for 24±2 hrs.			
		Appearance	No defects or abnormalities	The capacito	r should b	oe subjected to	5 temperature
		Capacitance Change	Within ±7.5%	cycles.	Tempe	erature (°C)	Time (min)
		D.F.	0.01 max.	1	-	55±3	30±3
13	Temperature			2		m Temp.	3 max.
13	Cycle	Insulation Resistance	More than 10,000M Ω or 100M $\Omega \cdot \mu F$ (Whichever is smaller)	3 4		25±3 m Temp.	30±3 3 max.
		Dielectric Strength (Between Terminals)	No defects or abnormalities	Pretreatment Perform a heat treatment at 150+0/-10°C for 1 hr., ar then let sit at room temperature for 24±2 hrs.		10°C for 1 hr., and	
		Appearance	No defects or abnormalities	Set the capacitor at 40±2°C and relative humidity to 95% for 500 $^{+24}_{-0}$ hrs. Remove and set for 24±2 at room temperature, then measure.		tive humidity of 90	
	Humidity	Capacitance Change	Within ±12.5%			d set for 24±2 hrs.	
14	(Steady State)	D.F.	0.02 max.	Pretreatment			
	C.u.o,	Insulation Resistance	More than 1,000M Ω or 10M Ω · μ F (Whichever is smaller)	Perform a heat treatment at 150+0/-10°C for 1 hr., a then let sit at room temperature for 24±2 hrs.			
		Appearance	No defects or abnormalities	Apply the rated voltage at 40±2°C and relative humidi of 90 to 95% for 500 ±24 hrs. Remove and set for 24±2 hrs. at room temperature, then measure. (Charge/Discharge current ≤ 50mA) • Pretreatment Perform a heat treatment at 150+0/-10°C for 1 hr., ar then let sit at room temperature for 24±2 hrs.		d relative humidity	
	Humidity	Capacitance Change	Within ±12.5%			ve and set for measure.	
15	Load	D.F.	0.02 max.				
		Insulation Resistance	More than 1,000M Ω or 10M Ω · μ F (Whichever is smaller)				
		Appearance	No defects or abnormalities			for 1000 ±48	
		Capacitance Change	Within ±12.5%	maximum operating temperature. Remove and set for 24±2 hrs. at room temperature, then measure. (Charge/Discharge current ≤ 50mA)			
		D.F.	0.02 max.	l `			
16	High Temperature Load	Insulation Resistance	More than 1,000M Ω or 10M Ω · μF (Whichever is smaller)	Rated Voltage Test Voltage DC250V 150% of the rated volta DC450V 130% of the rated volta DC630V 120% of the rated volta • Pretreatment Apply test voltage for 1 hr., at test temperature. Fand set for 24±2 hrs. at room temperature.		rated voltage rated voltage rated voltage	
		Appearance	No defects or abnormalities	The capacito	r should h	oe fully immers	sed. unagitated. in
17	Solvent Resistance	Marking	Legible	The capacitor should be fully immersed, unagitated reagent at 20 to 25°C for 30±5 sec. and then remo gently. Marking on the surface of the capacitor sho immediately be visually examined. Reagent: Isopropyl alcohol			and then removed

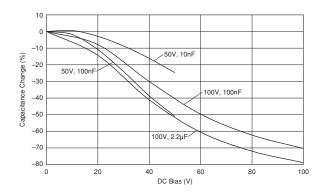


RCE Series Characteristics Reference Data (Typical Example)

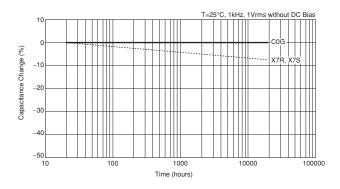
■ Capacitance - Temperature Characteristics



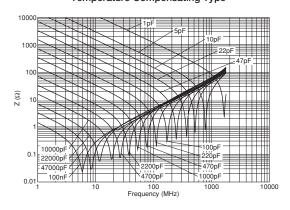
■ Capacitance - DC Voltage Characteristics



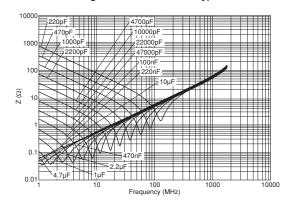
■ Capacitance Change - Aging



■ Impedance - Frequency Characteristics Temperature Compensating Type

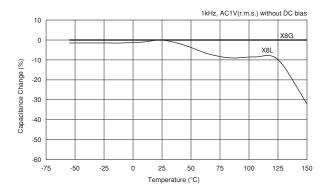


High Dielectric Constant Type

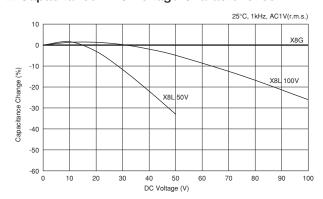


RHE Series Characteristics Reference Data (Typical Example)

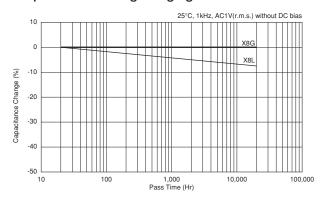
■ Capacitance - Temperature Characteristics



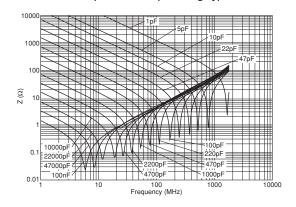
■ Capacitance - DC Voltage Characteristics



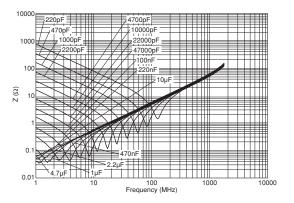
■ Capacitance Change - Aging



■ Impedance - Frequency Characteristics Temperature Compensating Type

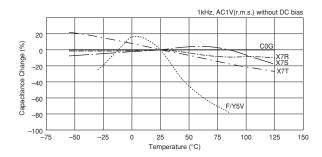


High Dielectric Constant Type



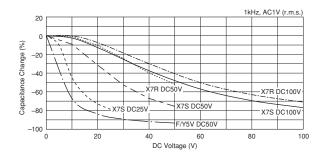
RDE Series Characteristics Reference Data (Typical Example)

■ Capacitance - Temperature Characteristics

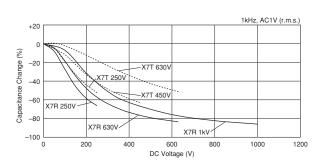


■ Capacitance - DC Voltage Characteristics

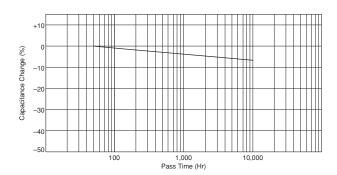
Rated Voltage: DC25V to DC100V



Rated Voltage: DC250V to DC1kV

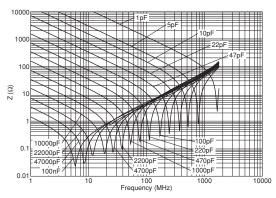


■ Capacitance Change - Aging

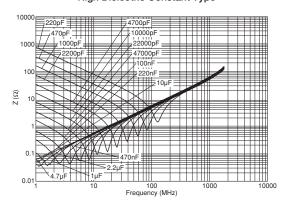


■ Impedance - Frequency Characteristics

Temperature Compensating Type



High Dielectric Constant Type





Packaging

Packaging

Two types of packaging for monolithic ceramic capacitors are available.

1. Bulk Packaging

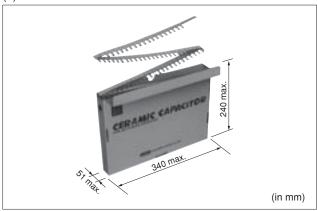
Minimum Quantity

Dimensions Code	Dimensions (LXW)	Minimum Quantity (pcs./Bag)
0	3.6×3.5mm or 4.0×3.5mm or 5.0×3.5mm (Depends on Part Number List)	
1	4.0×3.5mm or 4.5×3.5mm or 5.0×3.5mm (Depends on Part Number List)	
2	5.5×4.0mm	
3	5.5×5.0mm	500
4	7.5×5.5mm	
5	7.5×7.5mm (DC630V: 7.5×8.0mm)	
W	5.5×7.5mm or 6.0×8.0mm (Depends on Part Number List)	
U	7.7×12.5mm (DC630V: 7.7×13.0mm)	200

Please order with an integral multiple of the minimum quantity above.

2. Tape Carrier Packaging

(1) Dimensions of Ammo Pack



(2) Minimum Quantity

Dimensions Code	Dimensions (L×W)	Minimum Quantity (pcs./Ammo Pack)	
0	4.0×3.5mm or 5.0×3.5mm (Depends on Part Number List)		
1	4.0×3.5mm or 4.5×3.5mm or 5.0×3.5mm (Depends on Part Number List)	2000* ¹	
2	5.5×4.0mm	2000**	
3	5.5×5.0mm		
5	7.5×7.5mm (DC630V: 7.5×8.0mm)	2000*2	
6	10.0×10.0mm		
8	7.5×5.5mm	1500	
W	5.5×7.5mm or 6.0×8.0mm (Depends on Part Number List)		
U	7.7×12.5mm (DC630V: 7.7×13.0mm)	1000*3	

Please order with an integral multiple of the minimum quantity above.

*1 1500 pcs. for RDER71H335K3 C03A, RDEC71E226K3 C03A, RDEC72A155K3 C03A, RDEC72A225K3 C03A (Two blank columns are filled with the lead style code.)

*2 1500 pcs. for RDE Series

*3 1500 pcs. for RDED72W105MUE1H03A, RDER72E105MUE1H03A, RDER72J474MUE1K03A

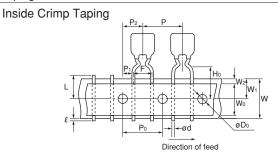
"Minimum Quantity" means the numbers of units of each delivery or order. The quantity should be an integral multiple of the "minimum quantity." (Please note that the actual delivery quantity in a package may change sometimes.)



Packaging

Continued from the preceding page.

■ Taping Dimensions



Dimensions and Lead style code	Dimensions (LXW)
0M1	3.6×3.5mm or 4.0×3.5mm
1M1	4.0×3.5mm or 4.5×3.5mm (Depends on Part Number List)
2M1	5.5×4.0mm
2M2	5.5×4.011111
3M1	5.5×5.0mm
3M2	5.5×5.011111
4M1	7.5×5.5mm
4140	/.5∧5.5IIIII

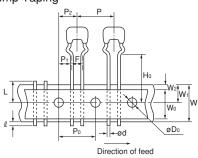
5.5×7.5mm

Straight Taping Direction of feed

Dimensions and Lead style code	Dimensions (LXW)
0DB	3.6×3.5mm
1DB	4.0×3.5mm
2DB	5.5×4.0mm
3DB	5.5×5.0mm
5E1	7.5×7.5mm
5E2	(DC630V, DC1kV: 7.5×8.0mm)
UE1	7.7×12.5mm (DC630V, DC1kV: 7.7×13.0mm)

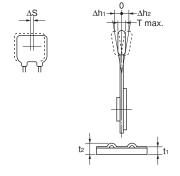
Outside Crimp Taping

4M2 WM1



Dimensions and Lead style code	Dimensions (LXW)
0S1	5.0×3.5mm
1S1	5.0×3.511111
2S1	5.5×4.0mm
2S2	5.5×4.011111
3S1	E EVE Onem
3S2	5.5×5.0mm

Item	Code	Dimensions (mm)
Pitch of Component	Р	12.7±1.0
Pitch of Sprocket Hole	P ₀	12.7±0.2
Local Occasions	_	2.5 ^{+0.4} _{-0.2} (DB) (S1) (S2)
Lead Spacing	F	5.0 +0.6
Length from Hole Center to		0.05.1.0
Component Center	P ₂	6.35±1.3
Length from Hole Center to	P ₁	3.85±0.7
Lead		5.1±0.7 (DB) (S1) (S2)
Leau	254±1.5	5 Total length of components pitch \times 20
Body Dimension	De	pends on Part Number List
Deviation Along Tape, Left	ΔS	±2.0
or Right Defect		±2.0
Carrier Tape Width	W	18.0±0.5
Position of Sprocket Hole	W ₁	9.0 ⁺⁰ _0.5
Lead Distance between	Ho	16.0±0.5 (M1) (S1)
Reference and Bottom Plane	ПО	20.0±0.5 (M2) (S2)
For Straight Lead Type	Н	20±0.5 (E2),17.5±0.5 (E1),16±0.5 (DB)
Diameter of Sprocket Hole	D ₀	4.0±0.1
Lead Diameter	d	0.5±0.05
Total Tape Thickness	t1	0.6±0.3
Total Thickness of Tape	t ₂	1.5 max.
and Lead Wire	l2	I.S IIIax.
Body Thickness	Т	Depends on Part Number List
Deviation Across Tape	∆h1	1.0 max.
Deviation Across Tape	∆h2	(Dimensions code W, U: 2.0 max.)
Portion to Cut in Case of	L	11.0 +0
Defect	_	-1.0
Protrusion Length	l	0.5 max.
Hold Down Tape Width	Wo	9.5 min.
Hold Down Tape Position	W2	1.5±1.5
Coating Extension	[Depends on Dimensions



1 Caution

■ **①**Caution (Storage and Operating Condition)

Operating and storage environment

The insulating coating of capacitors does not form a perfect seal; therefore, do not use or store capacitors in a corrosive atmosphere, especially where chloride gas, sulfide gas, acid, alkali, salt or the like are present. Also avoid exposure to moisture. Before cleaning, bonding or molding this product, verify that these processes do not affect product quality by testing the performance of a cleaned, bonded or molded product in the intended

equipment. Store the capacitors where the temperature and relative humidity do not exceed 5 to 40 degrees centigrade and 20 to 70%.

Use capacitors within 6 months after delivery.

FAILURE TO FOLLOW THE ABOVE CAUTIONS MAY RESULT, WORST CASE, IN A SHORT CIRCUIT AND CAUSE FUMING OR PARTIAL DISPERSION WHEN THE PRODUCT IS USED.

■ ①Caution (Rating)

1. Operating Voltage

When DC-rated capacitors are to be used in AC or ripple current circuits, be sure to maintain the Vp-p value of the applied voltage or the V0-p which contains DC bias within the rated voltage range.

When the voltage is applied to the circuit, starting or stopping may generate irregular voltage for a transit period because of resonance or switching. Be sure to use a capacitor with a rated voltage range that includes these irregular voltages. When DC-rated capacitors are to be used in input circuits from commercial power source (AC filter), be sure to use Safety Recognized Capacitors because various regulations on withstand voltage or impulse withstand established for all equipment should be taken into consideration.

Voltage	DC Voltage	DC+AC Voltage	AC Voltage	Pulse Voltage (1)	Pulse Voltage (2)
Positional Measurement	V0-p	Vo-p	Vp-p	Vp-p	Vp-p

$\hbox{2. Operating Temperature and Self-generated Heat}\\$

Keep the surface temperature of a capacitor below the upper limit of its rated operating temperature range. Be sure to take into account the heat generated by the capacitor itself. When the capacitor is used in a high-frequency current, pulse current or similar current, it may have self-generated heat due to dielectric loss. In the case of "High Dielectric Constant Type Capacitors," applied voltage load should be such that self-generated heat is within 20 °C under the condition where the capacitor is subjected at an atmosphere temperature of 25 °C. Please contact us if self-generated heat occurs with "Temperature Compensating Type Capacitors". When measuring, use a thermocouple of small thermal capacity -K of ø0.1mm under conditions where the capacitor is not affected by radiant heat from other components or wind from surroundings. Excessive heat may lead to deterioration of the capacitor's characteristics and reliability. Never attempt to perform measurement with the cooling fan running. Otherwise, accurate measurement cannot be ensured.

3. Fail-Safe

Be sure to provide an appropriate fail-safe function on your product to prevent a second damage that may be caused by the abnormal function or the failure of our product.

FAILURE TO FOLLOW THE ABOVE CAUTIONS MAY RESULT, WORST CASE, IN A SHORT CIRCUIT AND CAUSE FUMING OR PARTIAL DISPERSION WHEN THE PRODUCT IS USED.



⚠ Caution

■ ①Caution (Soldering and Mounting)

Vibration and impact
 Do not expose a capacitor or its leads to excessive shock or vibration during use.

2. Soldering

When soldering this product to a PCB/PWB, do not exceed the solder heat resistance specification of the capacitor. Subjecting this product to excessive heating could melt the internal junction solder and may result in thermal shocks that can crack the ceramic element.

Bonding, resin molding and coating
 In case of bonding, molding or coating this product, verify that these processes do not affect the quality of the capacitor by testing the performance of the bonded, molded or coated product in the intended equipment.

In case the amount of application, dryness/ hardening conditions of adhesives and molding resins containing organic solvents (ethyl acetate, methyl ethyl ketone, toluene, etc.) are unsuitable, the outer coating resin of a capacitor may be damaged by the organic solvents and may result, worst case, in a short circuit.

The variation in thickness of adhesive or molding resin or coating may cause an outer coating resin cracking and/or ceramic element cracking of a capacitor in a temperature cycling.

4. Treatment after bonding, resin molding and coating When the outer coating is hot (over 100 degrees centigrade) after soldering, it becomes soft and fragile, so please be careful not to give it mechanical stress.

FAILURE TO FOLLOW THE ABOVE CAUTIONS MAY RESULT, WORST CASE, IN A SHORT CIRCUIT AND CAUSE FUMING OR PARTIAL DISPERSION WHEN THE PRODUCT IS USED.

■ **(**Caution (Handling)

Vibration and impact

Do not expose a capacitor or its leads to excessive shock or vibration during use.

FAILURE TO FOLLOW THE ABOVE CAUTIONS MAY RESULT, WORST CASE, IN A SHORT CIRCUIT AND CAUSE FUMING OR PARTIAL DISPERSION WHEN THE PRODUCT IS USED.



Notice

■ Notice (Rating)

Capacitance change of capacitor
In case of F/X7R/X7S/X7T/X8L/Y5V char.
Capacitors have an aging characteristic, whereby the capacitor continually decreases its capacitance slightly if the capacitor is left on for a long time. Moreover, capacitance might change greatly depending on the surrounding temperature or an applied voltage.

■ Notice (Soldering and Mounting)

1. Cleaning (ultrasonic cleaning)

To perform ultrasonic cleaning, observe the following conditions.

Rinse bath capacity: Output of 20 watts per liter or less.

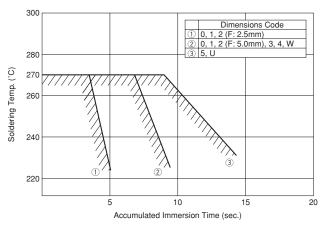
Rinsing time: 5 min. maximum.

Do not vibrate the PCB/PWB directly.

Excessive ultrasonic cleaning may lead to fatigue destruction of the lead wires.

2. Soldering and Mounting

(1) Allowable Conditions for Soldering Temperature and Time



Perform soldering within tolerance range (shaded portion).

(2) Insertion of the Lead Wire

- When soldering, insert the lead wire into the PCB without mechanically stressing the lead wire.
- Insert the lead wire into the PCB with a distance appropriate to the lead space.



⚠Note:

1. Export Control

<For customers outside Japan>

No Murata products should be used or sold, through any channels, for use in the design, development, production, utilization, maintenance or operation of, or otherwise contribution to (1) any weapons (Weapons of Mass Destruction [nuclear, chemical or biological weapons or missiles] or conventional weapons) or (2) goods or systems specially designed or intended for military end-use or utilization by military end-users.

For products which are controlled items subject to the "Foreign Exchange and Foreign Trade Law" of Japan, the export license specified by the law is required for export.

- 2. Please contact our sales representatives or product engineers before using the products in this catalog for the applications listed below, which require especially high reliability for the prevention of defects which might directly damage a third party's life, body or property, or when one of our products is intended for use in applications other than those specified in this catalog.
 - Aircraft equipment
- ② Aerospace equipment④ Power plant equipment
- ③ Undersea equipment⑤ Medical equipment
- 6 Transportation equipment (vehicles, trains, ships, etc.)
- Traffic signal equipment
- Data-processing equipment
 On Application of similar complexity and/or reliability requirements to the applications listed above
- 3. Product specifications in this catalog are as of January 2014. They are subject to change or our products in it may be discontinued without advance notice.

 Please check with our sales representatives or product engineers before ordering. If there are any questions, please contact our sales representatives or product engineers.
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- 5. This catalog has only typical specifications. Therefore, please approve our product specifications or transact the approval sheet for product specifications before ordering.
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International Division

7. No ozone depleting substances (ODS) under the Montreal Protocol are used in our manufacturing process.



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